



## **Features**

- Up to Eight Low-Noise PGAs and Eight High Resolution Simultaneous-Sampling ADCs
- Input-Referred Noise: 1 µVPP (70-Hz BW)
- Input Bias Current: 300 pA
- Data Rate: 250 SPS to 16 kSPS
- CMRR: –110 dB
- Programmable Gain: 1, 2, 4, 6, 8, 12, or 24
- Unipolar or Bipolar Supplies:
  - Analog: 4.5 V to 5.5 V
  - Digital: 1.8 V to 3.3 V
- Built-In Bias Drive Amplifier,
- Lead-Off Detection, Test Signals
- Built-In Oscillator
- Internal or External Reference
- Flexible Power-Down, Standby Mode
- Pin-Compatible with the ADS129x
- SPI-Compatible Serial Interface
- Operating Temperature Range: –40°C to +85°C

## **Applications**

- Medical Instrumentation Including:
  - Electroencephalogram (EEG) Study
  - Fetal Electrocardiography (ECG)
  - Sleep Study Monitor
  - Bispectral Index (BIS)
  - Evoked Audio Potential (EAP)



## **General Description**

The CBM24AD99Q-4, CBM24AD99Q-6, and CBM24AD99Q devices are a family of four-, six-, and eight-channel, lownoise, 24-bit, simultaneous-sampling delta-sigma ( $\Delta\Sigma$ ) analog-to-digital converters (ADCs) with a built-in programmable gain amplifier (PGA), internal reference, and an onboard oscillator. The CBM24AD99Q-x incorporates all commonly-required features for extracranial electroencephalogram (EEG) and electrocardiography (ECG) applications. With its high levels of integration and exceptional performance, the CBM24AD99Q-x enables the creation of scalable medical instrumentation systems at significantly reduced size, power, and overall cost. The CBM24AD99Q-x has a flexible input multiplexer per channel that can be independently connected to the internally-generated signals for test, temperature, and lead-off detection. Additionally, any configuration of input channels can be selected for derivation of the patient bias output signal. Optional SRB pins are available to route a common signal to multiple inputs for a referential montage configuration. The CBM24AD99Q-x operates at data rates from 250 SPS to 16 kSPS. Lead-off detection can be implemented internal to the device using an excitation current sink or source. Multiple CBM24AD99Q-4, CBM24AD99Q-6, or CBM24AD99Q devices can be cascaded in high channel count systems in a daisy-chain configuration. The CBM24AD99Q-x is offered in a TQFP-64 package specified from -40°C to +85°C.

### CBM24AD99Q OPERATION INSTRUCTION



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OPERATION INSTRUCTION

# **Functional Block Diagram**

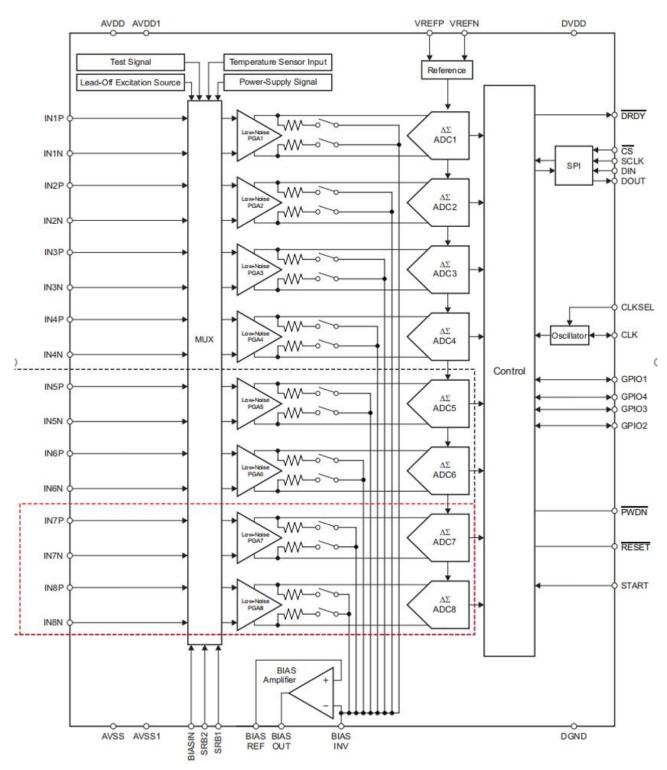


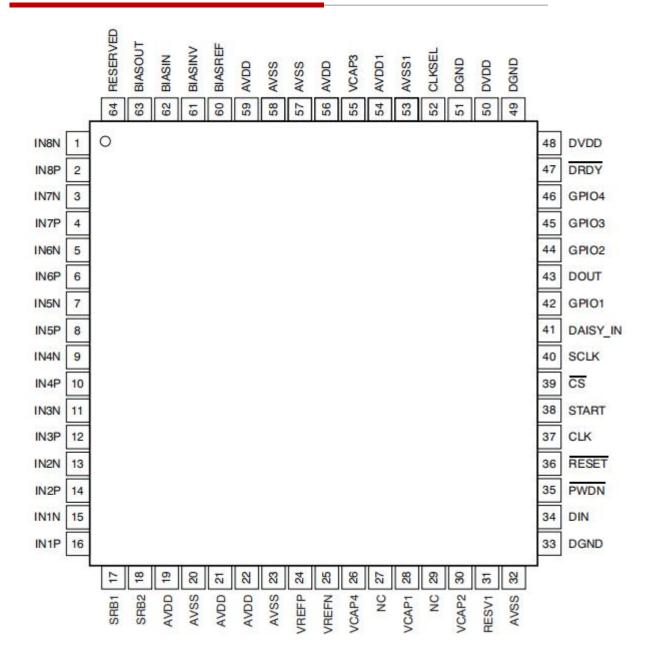
Figure 1. Functional Block Diagram



## **Product comparison**

Model	Package	Temperature	Channel	Resolution	Maximum sampling rate
CBM24AD99Q	TQFP-64	-40℃~85℃	8	24	16kSPS
CBM24AD98Q	TQFP-64	-40℃~85℃	8	24	32kSPS

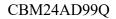
## **Pin configuration and functions**





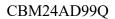
#### OPERATION INSTRUCTION

	PIN	ТҮРЕ	DESCRIPTION
NO.	NAME		
	19,21,22,56,59	Supply	Analog supply. Connect a 1-µF capacitor to AVSS.
AVDD	59	Supply	Charge pump analog supply. Connect a $1-\mu F$ capacitor to AVSS, pin 58.
AVDD1	54	Supply	Analog supply. Connect a 1-µF capacitor to AVSS1.
AVSS	20,23,32,57	Supply	Analog ground
AV33	58	Supply	Analog ground for charge pump
AVSS1	53	Supply	Analog ground
BIASIN	62	Analog input	Bias drive input to MUX
BIASINV	61	Analog input/output	Bias drive inverting input
BIASOUT	63	Analog output	Bias drive output
BIASREF	60	Analog input	Bias drive noninverting input
CS	39	Digital input	Chip select, active low
CLK	37	Digital input	Master clock input
CLKSEL	52	Digital input	Master clock select
DAISY_IN	41	Supply	Daisy-chain input;
DGND	33,49,51	Digital input	Digital ground
DIN	34	Digital input	Serial data input
DOUT	43	Digital output	Serial data output
DRDY	47	Digital output	Data ready; active low
DVDD	48,50	Supply	Digital power supply. Connect a 1-µF capacitor to DGND.
GPIO1	42	Digital	General-purpose input/output pin 1.
GPIOT	42	input/output	Connect to DGND with a $\geq 10$ -k $\Omega$ resistor if unused.
GPIO2	44	Digital	General-purpose input/output pin 2.
GHOZ		input/output	Connect to DGND with a $\geq 10$ -k $\Omega$ resistor if unused.
GPIO3	45	Digital	General-purpose input/output pin 3.
		input/output	Connect to DGND with a $\geq 10$ -k $\Omega$ resistor if unused.
GPIO4	46	Digital	General-purpose input/output pin 4.
		input/output	Connect to DGND with a $\geq 10$ -k $\Omega$ resistor if unused.
IN1N	15	Analog input	Differential analog negative input 1





IN1P	16	Analog input	Differential analog positive input 1
IN2N	13	Analog input	Differential analog negative input 2
IN2P	14	Analog input	Differential analog positive input 2
IN3N	11	Analog input	Differential analog negative input
IN3P	12	Analog input	Differential analog positive input 3
IN4N	9	Analog input	Differential analog negative input 4
IN4P	10	Analog input	Differential analog positive input 4
IN5N	7	Analog input	Differential analog negative input 5(limited to CBM24AD99Q-6 and CBM24AD99Q)
IN5P	8	Analog input	Differential analog positive input 5(limited to CBM24AD99Q-6 and CBM24AD99Q)
IN6N	5	Analog input	Differential analog negative input 6(limited to CBM24AD99Q-6 and CBM24AD99Q)
IN6P	6	Analog input	Differential analog positive input 6(limited to CBM24AD99Q-6 and CBM24AD99Q)
IN7N	3	Analog input	Differential analog negative input 7(limited to CBM24AD99Q)
IN7P	4	Analog input	Differential analog positive input 7(limited to CBM24AD99Q)
IN8N	1	Analog input	Differential analog negative input 8(limited to CBM24AD99Q)
IN8P	2	Analog input	Differential analog positive input 8(limited to CBM24AD99Q)
NC	27,29		No connection, leave as open circuit
Reserved	64	Analog output	Reserved for future use, leave as open circuit
RESET	36	Digital input	System reset, active low
RESV1	31	Digital input	Reserved for future use; must tie to logic low (DGND).
SCLK	40	Digital input	Serial clock input
SRB1	17	Analog input/output	Patient stimulus, reference, and bias signal 1
SRB2	18	Analog input/output	Patient stimulus, reference, and bias signal 2





START	38	Digital input	Synchronization signal to start or restart a conversion
PWDN	35	Digital input	Power-down pin; active low
VCAP1	28	Analog output	Analog bypass capacitor; connect 100-µF capacitor to AVSS
VCAP2	30	Analog output	Analog bypass capacitor; connect 1-µF capacitor to AVSS
VCAP3	55	Analog output	Analog bypass capacitor pin. Connect a parallel combination of 1-µF and 0.1-µF capacitors to AVSS.
VCAP4	26	Analog output	Analog bypass capacitor; connect 1-µF capacitor to AVSS
VREFN	25	Analog input	Negative reference voltage
VREFP	24	Analog input/output	Positive analog reference voltage. Connect a minimum 10-µF capacitor to VREFN.

## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

	MIN	MAX	UNIT
AVDD to AVSS	-0.3	5.5	V
DVDD to DGND	-0.3	3.9	V
AVSS to DGND	-3	0.2	V
VREFP input to AVSS	AVSS-0.3	AVDD+0.3	V
Analog input voltage	AVSS-0.3	AVDD+0.3	V
Digital input voltage	DGND-0.3	DVDD+0.3	V
Digital output voltage	DGND-0.3	DVDD+0.3	V
Input, continuous, any pin except power supply pins <sup>(2)</sup> current	-10	10	mA
Junction temperature, TJ		150	°C
Storage temperature, Tstg	-60	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



(2) Input pins are diode-clamped to the power-supply rails. Limit the input current to 10 mA or less if the analog input voltage exceeds AVDD + 0.3 V or is less than AVSS – 0.3 V, or if the digital input voltage exceeds DVDD + 0.3 V or is less than DGND – 0.3 V.

## ESD

			UNIT
V <sub>(ESD)</sub> Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins(1)	±2000	V
	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins(2)	±500	V

## **Recommended Operating conditions**

over operating ambient temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
POWER SUPPLY					
Analog power supply (AVDD – AVSS)	Analog power supply (AVDD – AVSS)		5	5.25	V
Digital power supply (DVDD)		1.8	1.8	3.6	V
AVDD – DVDD		-2.1		3.6	V
ANALOG INPUTS					
Full-scale differential input voltage ran	ge (AINP – AINN)	$\pm V_{REF} / 0$	Gain		V
Common-mode input voltage		See the	9.3.3		
VOLTAGE REFERENCE INPUTS					
Differential reference voltage	VREF = (VREFP - VREFN)		4.5		V
Negative input (VREFN)			AVSS		V
Positive input (VREFP)			AVSS		v
Positive input (VREFP)			+ 4.5		v
CLOCK INPUT					
External clock input frequency	CLKSEL pin = 0	1.5	2.048	2.25	MHz
DIGITAL INPUTS					1
Less AVelles es		DGND		DVDD	
Input Voltage		-0.1		+0.1	V
TEMPERATURE RANGE					
Operating temperature range	Industrial grade	-40		85	°C



## **Thermal information**

		CBM24AD99Q	11
	THERMAL METRIC(1)	PAG(TQFP) 64PIN	Unit
$R_{\theta JA}$	Junction-to-ambient thermal resistance	46.2	°C/W
$R_{\theta JC(TOP)}$	Junction-to-case (top) thermal resistance	5.8	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	19.6	°C/W
τιΨ	Junction-to-top characterization parameter	0.2	°C/W
ψ <sub>ЈВ</sub>	Junction-to-board characterization parameter	19.2	°C/W
$R_{\theta JC(bot)}$	Connected to the shell (bottom) thermal resistance	Not applicable	°C/W

## **Electrical Characteristics**

Minimum and maximum specifications apply from  $T_A = -40$ °C to 85°C. Typical specifications are at  $T_A = +25$ °C. All specifications are at AVDD – AVSS = 5 V, DVDD = 3.3 V, V<sub>REF</sub> = 4.5 V, external f<sub>CLK</sub> = 2.048 MHz, data rate = 250 SPS, and gain = 12 (unless otherwise noted)

Parameter	Test Conditions	Min	Тур.	Мах	Unit
ANALOG INPUTS					
Input capacitance			20		рF
Input bing gurrant	$T_A$ = +25°C, InxP and INxN = 2.5 V			±300	pА
Input bias current	$T_A = -40^{\circ}$ C to +85°C, InxP and INxN = 2.5 V		±300		nA
	No lead-off	1000			MΩ
DC input impedance	Current source lead-off detection		500		MΩ
PGA PERFORMANCE					
Gain settings		1,2,3,4,6,8,12,24			
Bandwidth		See PEA explain			
ADC PERFORMANCE					
Resolution	Data rates up to 8 kSPS, no missing codes	24			Bits
Data rate	f <sub>CLK</sub> = 2.048 MHz, LP mode	250		16000	SPS
DC CHANNEL PERFORMAN	CE				
Input-referred noise	10 seconds of data, gain = $24(1)$		1		$\mu V_{PP}$
	250 points, 1 second of data, gain = 24, TA = +25°C		1	1.35	$\mu V_{PP}$



#### **OPERATION INSTRUCTION**

	250 points, 1 second of data, gain = 24, TA = $-40^{\circ}$ C to $+85^{\circ}$ C		1	1.6	$\mu V_{PP}$
	All other sample rates and gain settings		See Noise easurements section		
Integral nonlinearity	Full-scale with gain = 12, best fit		8		ppm
Offset error			60		μV
Offset error drift			80		µV/℃
Gain error	Excluding voltage reference error		0.1	±0.5	%of FS
Gain drift	Excluding voltage reference drift		3		ppm/°C
Gain match between channels			0.2		%of FS
AC CHANNEL PERFORMAN	ICE				
CMRR Common-mode rejection ratio	$f_{CM} = 50 \text{ Hz and } 60 \text{ Hz}(2)$	-110	-120		dB
PSRR Power-supply rejection ratio	$f_{PS} = 50 \text{ Hz} \text{ and } 60 \text{ Hz}$		96		dB
Crosstalk	$f_{IN} = 50 \text{ Hz} \text{ and } 60 \text{ Hz}$		-110		dB
SNR Signal-to-noise ratio	$V_{IN} = -2 \text{ dBFs}, f_{IN} = 10 \text{-Hz} \text{ input, gain} = 12$		121		dB
THD Total harmonic distortion	$V_{IN} = -0.5 \text{ dBFs}, f_{IN} = 10 \text{ Hz}$		-99		dB
PATIENT BIAS AMPLIFIER			1	1	
Integrated noise	BW = 150 Hz		2		$\mu V_{RMS}$
Gain bandwidth product	50-kΩ    10-pF load, gain = 1		100		kHz
Slew rate	50-kΩ    10-pF load, gain = 1		0.07		V/µs
THD Total harmonic distortion	f <sub>IN</sub> = 10 Hz, gain = 1		-80		dB
Common-mode input range		AVSS +0.3		AVDD -0.3	V
Short-circuit current			1.1		mA
Quiescent power consumption			2.0		μΑ



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(1) Noise data measured in a 10-second interval. Test not performed in production. Input-referred noise is calculated with the input shorted (without electrode resistance) over a 10-second interval.

(2) CMRR is measured with a common-mode signal of AVSS + 0.3 V to AVDD – 0.3 V. The values indicated are the minimum of the eight

Parameter	Test Conditions	Min	Тур.	Мах	Unit
LEAD-OFF DETECT					
Frequency	Continuous	Registe	At dc, f <sub>DR</sub> / 4, see Register Definition for settings		Hz
	One time or periodic		7.8,31.2		
	ILEAD_OFF[1:0] = 00		6		nA
Current	ILEAD_OFF[1:0] = 01		24		
Current	ILEAD_OFF[1:0] =10		6		
	ILEAD_OFF[1:0] = 11		24		μA
Current accuracy			±20%		
Comparator threshold			±30		mV
accuracy			±50		mv
EXTERNAL REFERENCE					
Input impedance			5.6		kΩ
INTERNAL REFERENCE					
VREF			4.5		V
V <sub>REF</sub> accuracy			± 0.2%		
Internal reference drift	$TA = -40^{\circ}C \text{ to } 85^{\circ}C$		35		ppm/°C
Start-up time			150		ms
SYSTEM MONITORS					
Analog-supply reading error			2%		
Digital-supply reading error			2%		
Duringual	From power up to DRDY low		150		ms
Device wake up	STANDBY mode		31.25		μs



**OPERATION INSTRUCTION** 

Temperature-sensor reading,voltage	TA = 25°C			145		mV
Temperature-sensor						
reading,coefficient				490		µV/°C
Test-signal frequency				f <sub>CLK</sub> / 2 <sup>21</sup> , f <sup>CLK</sup> / 2 <sup>20</sup>		Hz
Test-signal voltage				±1,±2		mV
Test-signal accuracy				±2%		
CLOCK				<u> </u>		
Internal-oscillator clock frequency	Nominal frequency		2.048		MHz	
	T <sub>A</sub> = 25°C				±0.5%	
Internal clock accuracy	$-40^{\circ}C \le T_{A} \le 85^{\circ}C$ , incomply	-		±2.5%		
Internal-oscillator start-up time					20	μs
Internal-oscillator power consumption				120		μW
DIGITAL INPUT/OUTPUT (D	VDD = 1.65 V to 3.6 V	)	1			
VIH High-level inpout voltage			0.8D VDD		DVDD +0.1	V
VIL Low-level input voltage			-0.1		0.2DV DD	V
VOH High-level output voltage	I <sub>OH</sub> = -500 μA	0.9D VDD			V	
VOL Low-level output voltage	I <sub>o</sub> L = 500 μA		-	0.1DV DD	v	
IIN Input current	0 V < V <sub>DigitalInput</sub> < DVD	-10		10	μA	
SUPPLY CURRENT (Bias Tur	ned Off)					
	CBM24AD99Q-4	Normal mode, AVDD		4.06		mA
I <sub>AVDD</sub> AVDD current	CBM24AD99Q-6	– AVSS = 5 V		5.57		mA



OPERATION INSTRUCTION

	CBM24AD99Q			7.14	-	mA
	CBM24AD99Q-4	Normal mode,		0.54		mA
	CBM24AD99Q-6	DVDD = 3.3 V		0.66		mA
	CBM24AD99Q		-	1	-	mA
I <sub>DVDD</sub> DVDD current	CBM24AD99Q-4	Normal mode,		0.27		mA
	CBM24AD99Q-6	DVDD = 1.8 V		0.34		mA
	CBM24AD99Q	-		0.5		mA
POWER DISSIPATION (Anal	og Supply = 5 V, Bias /	Amplifiers Turned Off)				
	CBM24AD99Q-4	Normal mode		22		mW
		Power-down		10		
		Standby mode, internal reference	-	5.1	-	mW
		Normal mode		30		mW
Dower discipation		Power-down		10		
Power dissipation	CBM24AD99Q-6	Standby mode, internal reference	-	5.1	-	mW
		Normal mode		39		mW
		Power-down		10		
	CBM24AD99Q	Standby mode, internal reference		5.1		mW

## Timing requirement: SPI serial interface

Specifications apply from TA =  $-40^{\circ}$ C to  $+85^{\circ}$ C (unless otherwise noted); load on DOUT = 20 pF || 100 k $\Omega$ 

	2.7 V ≤ DVDD ≤ 3.6 V		1.8 V ±	UNIT	
			DVDD		
	MIN	MAX	MIN	ΜΑΧ	
t <sub>CLK</sub> Master clock period	414	666	414	666	ns
t <sub>cssc</sub> Delay time, CS low to first SCLK	6		17		ns
t <sub>SCLK</sub> SCLK period	50		66.6		ns
S <sub>PWH, L</sub> SCLK pulse width, high and low	15		25		ns
$t_{\mbox{\tiny DIST}}$ DIN valid to SCLK falling edge: setup time	10		10		ns

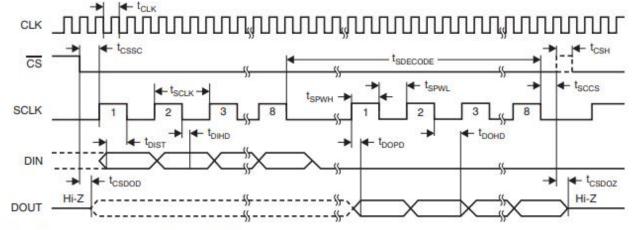


t <sub>DIHD</sub> Valid DIN after SCLK falling edge: hold time	10	 11	 ns
t <sub>CSH</sub> CS high pulse	2	 2	 t <sub>CLK</sub>
t <sub>SCCS</sub> Eighth SCLK falling edge to CS high	4	 4	 t <sub>CLK</sub>
t <sub>SDECODE</sub> Command decode time	4	 4	 t <sub>CLK</sub>
t <sub>DISCK2ST</sub> DAISY_IN valid to SCLK rising edge: setup time	10	 10	 ns
$t_{\text{DISCK2HT}}$ DAISY_IN valid after SCLK rising edge: hold time	10	 10	 ns

## Switch characteristics: Serial interface

Specifications apply from  $T_A = -40^{\circ}$ C to +85°C (unless otherwise noted). Load on DOUT = 20 pF || 100 k $\Omega$ .

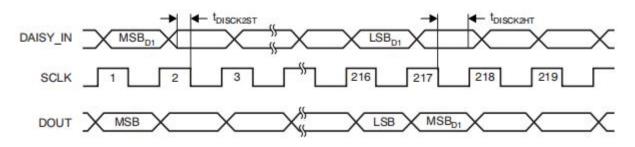
PARAMETER		2.7 V ≤	DVDD	1.65 V		
		≤ 3.6 V		$DVDD \leq 2V$		UNIT
		MIN	MAX	MIN	МАХ	
t <sub>DOHD</sub>	SCLK falling edge to invalid DOUT: hold time	10		10		ns
t <sub>DOPD</sub>	Propagation delay time, SCLK rising edge to DOUT valid		17		32	ns
t <sub>CSDOD</sub>	Propagation delay time, CS low to DOUT driven	10		20		ns
t <sub>csdoz</sub>	Propagation delay time, CS high to DOUT Hi-Z		10		20	ns



NOTE: SPI settings are CPOL = 0 and CPHA = 1.

Figure 7.1. Serial Interface Timing







## **Parameter measurement information**

#### **Noise measurement**

Optimizing the noise performance of the CBM24AD99Q channel can be achieved by adjusting the data rate and PGA gain. Both reducing the data rate and increasing the PGA gain lead to a reduction in input noise, which is particularly beneficial for measuring weak bioelectric potential signals. The following table presents the noise performance measurements of the CBM24AD99Q under conditions of a 5V analog supply and a 4.5V reference voltage. These figures represent the typical noise performance at a temperature (TA) of +25°C. The displayed data are the averaged readings from multiple chips and were taken with the input shorted. A minimum of 1,000 consecutive readings were used to compute the RMS ( $\mu$ VRMS) and peak-to-peak ( $\mu$ VPP) noise for each measurement. For lower data rates, the ratio between RMS and peak-to-peak noise is approximately 6.6.

				PGA GAIN = 1			PGA GAIN = 2					
DR BITS OF CONFIG1 REGISTER	OUTPUT DATA RATE (SPS)	-3-dB BANDWIDTH (Hz)	μV <sub>RMS</sub>	μV <sub>pp</sub>	DYNAMIC RANGE (dB)	NOISE- FREE BITS	ENOB	μV <sub>RM5</sub>	μV <sub>pp</sub>	DYNAMIC RANGE (dB)	NOISE- FREE BITS	ENOB
000	16000	4193	21.70	151.89	103.3	15.85	17.16	10.85	75.94	103.3	15.85	17.16
001	8000	2096	6.93	48.53	113.2	17.50	18.81	3.65	25.52	112.8	17.43	18.74
010	4000	1048	4.33	30.34	117.3	18.18	19.49	2.28	15.95	116.9	18.11	19.41
011	2000	524	3.06	21.45	120.3	18.68	19.99	1.61	11.29	119.9	18.60	19.91
100	1000	262	2.17	15.17	123.3	19.18	20.49	1.14	7.98	122.9	19.10	20.41
101	500	131	1.53	10.73	126.3	19.68	20.99	0.81	5.65	125.9	19.60	20.91
110	250	65	1.08	7.59	129.3	20.18	21.48	0.57	3.99	128.9	20.10	21.41
111	n/a	n/a		2 <del></del>	-	8 <del></del> 12	-	2 <del></del>	-	s <del></del> s	-	8 <del></del> 72

Table 8.1.Input-Referred Noise (µVRMS,	μVPP) in Normal Mode 5-V Analog Su	pply and 4.5-V Reference <sup>(1)</sup>



## **Detailed Description**

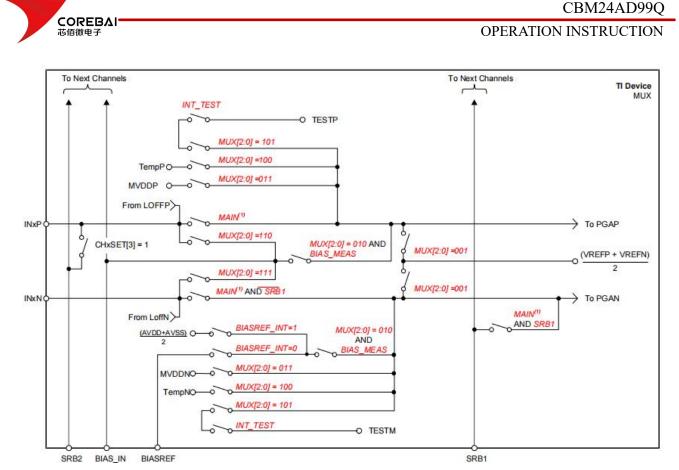
The CBM24AD99Q is a low-noise, low-power, multi-channel, simultaneous sampling, 24-bit, delta-sigma analog-to-digital converter (ADC) chip that integrates a programmable gain amplifier (PGA) and various electroencephalogram (EEG) specific features, making it highly suitable for electrocardiogram (ECG) and electroencephalogram (EEG) applications. By shutting off the power to the EEG-specific circuitry, these chips can also be used in high-performance, multi-channel data acquisition systems. This series of chips features a highly programmable multiplexer capable of performing temperature, power, input short circuit, and bias measurements. Additionally, the multiplexer allows any input electrode to be programmed as a reference driver. The PGA gain can be selected from seven settings (1, 2, 4, 6, 8, 12, and 24). The ADC within the chip offers data rates ranging from 250 SPS to 16 kSPS. Chip communication is accomplished using an SPI-compatible interface, and four general-purpose input/output (GPIO) pins are provided. Multiple chips can be synchronized using the START pin. An internal reference generates a low-noise 4.5 V internal voltage, and an internal oscillator produces a 2.048 MHz clock. A versatile patient bias drive module allows the selection of any combination of electrodes to generate a patient driving signal. Lead detection can be achieved through a current source.

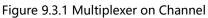
## **Function Description**

This section describes the internal functional information of the CBM24AD99Q. Here,  $f_{CLK}$  represents the frequency of the signal on the CLK pin,  $t_{CLK}$  denotes the period of the signal on the CLK pin,  $f_{DR}$  indicates the output data rate,  $t_{DR}$  signifies the output data time cycle, and  $f_{MOD}$  refers to the frequency at which the modulator samples the input.

### Input Multiplexer

In the CBM24AD99Q, each channel is equipped with an input multiplexer (depicted in Figure 9.3.1), offering flexible signal routing options through configuration. In the diagram, MAIN signifies the conditions where MUX[2:0] is set to 000, 110, or 111.

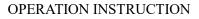




(1) Chip Noise Measurement Setting CHnSET[2:0] to 001 shorts the P/N terminals of the channel and sets a common-mode voltage of [(VVREFP + VVREFN)/2] for both channel inputs. This configuration can be utilized for testing the inherent noise of the chip.

(2) Test Signal (TestP and TestN) Configuring CHnSET[2:0] to 101 introduces an internally generated test signal to the P/N terminals of the channel. Details regarding the internal test signal can be found in the CONFIG2 register description.

(3) Temperature Sensor (TempP, TempN) The CBM24AD99Q incorporates an on-chip temperature sensor, which employs two internal diodes, with one diode having a current density sixteen times that of the other, as depicted in Figure 9.3.2. The disparity in diode current densities generates a voltage difference proportional to the absolute temperature. Owing to the low thermal resistance from the package to the printed circuit board (PCB), the internal chip temperature is closely correlated with the PCB temperature. Note that self-heating of the CBM24AD99Q can lead to internal temperature readings higher than the ambient temperature of the surrounding PCB. Setting CHnSET[2:0] to 100 routes the temperature sensor signals to the P/N terminals of the channel.





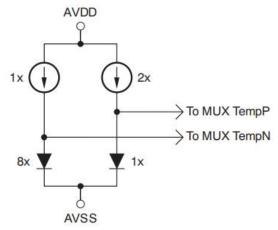


Figure 9.3.2 Illustration of Temperature Sensor Measurement Inputs

(4) Power Supply Measurement (MVDDP, MVDDN) Setting CHn

SET[2:0] to 011 configures the channel inputs to monitor different supply voltages of the chip. For channels 1, 2, 5, 6, 7, and 8, (MVDDP – MVDDN) equals  $[0.5 \times (AVDD + AVSS)]$ . For channels 3 and 4, (MVDDP – MVDDN) is DVDD / 4. To prevent PGA saturation during power supply measurement, set the gain to 1.

(5)Lead-Off Excitation Signals (LoffP, LoffN)

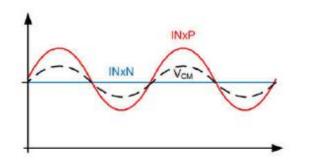
Lead-off excitation signals are fed into the multiplexer before switching. The comparators detecting lead-off conditions are also connected to the multiplexer prior to switching. For detailed explanation, refer to the Lead-off Detection section.

(6) Single-Ended Input Measurement Mode Setting CHnSET[2:0] to 011 or 111 routes the bias signal from the BIASIN pin to the designated electrode, enabling the channel to operate as a single-ended input channel. Setting CHnSET[2:0] to 010 and setting the BIAS\_MEAS bit in the CONFIG3 register to "1" measures the signal on the BIASIN pin relative to the voltage on the BIASREF pin.

#### 9.3.2 Analog Inputs

The analog inputs of the chip are connected to a low-noise, low-drift, high-input impedance programmable gain amplifier via a multiplexer. The CBM24AD99Q analog inputs are fully differential. The range of the differential input voltage (VINxP – VINxN) spans from –VREF/Gain to VREF/Gain. There are two methods to drive the analog inputs of the CBM24AD99Q: pseudo-differential or fully differential, as illustrated in Figure 9.3.3.





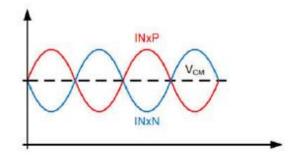


Figure 9.3.3 Pseudo-Differential (Left) and Fully Differential (Right) Driving Configurations Maintaining the INxN pin at a common voltage, ideally at the mid-supply level, constitutes a pseudo-differential input approach. The INxP pin is then swung around this common voltage between  $-V_{REF}$ /Gain and  $V_{REF}$ /Gain, while staying within the absolute maximum rating specifications. When configured for pseudo-differential mode, the common-mode voltage (VCM) will vary with the signal level changes, requiring that the differential signal at its minimum and maximum satisfy the common-mode input specification.Configuring the signals on INxP and INxN as inverse signals centered around a common-mode voltage (VCM) represents the fully differential input method. Both INxP and INxN inputs swing from a common voltage of  $+\frac{1}{2}$ VREF/Gain to a common voltage of  $-\frac{1}{2}$  VREF/Gain. The differential voltage at the peaks and troughs equals  $-V_{REF}$ /Gain to VREF/Gain, centered around a fixed common-mode voltage. For optimal performance, it is recommended to set the common-mode voltage at the midpoint of the analog supplies, i.e., [(AVDD + AVSS)/2].

### PGA settings and input range

The low-noise PGA is a differential-input and output amplifier whose gain settings (1, 2, 4, 6, 8, 12, and 24) can be configured by writing to the CHnSET register. As the CBM24AD99Q inputs are CMOS-based, current noise can be considered negligible. Table 9.3.1 presents typical bandwidth values for various gain settings. Please note that the table illustrates small-signal bandwidth; for large signals, performance is limited by the PGA's slew rate.

Obtain	Nominal bandwidth at room temperature
Obtain	(kHz)
1	662
2	332
4	165
6	110
8	83

#### Table 9.3.1 PGA Gain and Bandwidth



12	55
24	27

To maintain operation within the linear range of the PGA, input signals must comply with the following:

AVDD-0.2V-((Gain x  $V_{MAX_{DIFF}}$ ))/2>CM>AVSS+0.2V+((Gain x  $V_{MAX_{DIFF}}$ ))/2

Here,  $V_{MAX_DIFF}$  denotes the maximum differential input voltage of the PGA; CM represents the common-mode range. For instance: If AVDD = 5 V, Gain = 12, and VMAX\_DIFF = 350 mV, then 2.3 V < CM < 2.7 V. The differential input voltage range (VINxP – VINxN) is dependent on the analog supply and reference voltage used in the system as well as the gain, spanning from –  $V_{REF}$ /Gain to  $V_{REF}$ /Gain.

## **Δ**Σ Modulator

Each channel in the CBM24AD99Q features a 24-bit  $\Delta\Sigma$  Analog-to-Digital Converter (ADC). The converter utilizes a second-order modulator optimized for low-noise applications. The modulator samples the input signal at a rate of ( $f_{MOD} = f_{CLK}/2$ ), with the chip noise being shaped up to  $f_{MOD}/2$ , as illustrated in Figure 9.3.4.

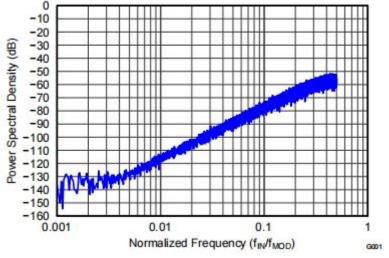
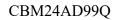


Figure 9.3.4 Modulator noise spectrum

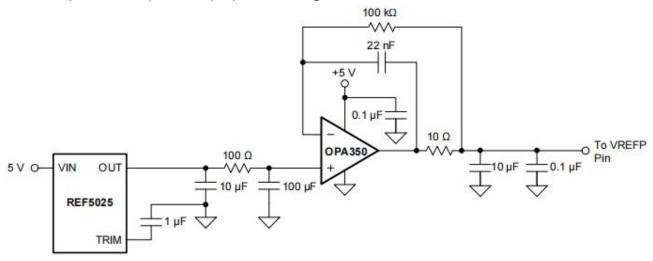
### **Reference Voltage**

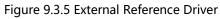
The CBM24AD99Q internally generates a reference voltage typically at 4.5V or 2.4V (based on AVSS), controlled by the VREF\_4V bit in the CONFIG3 register. When utilizing the internal reference voltage, VREFN should be connected to AVSS. The internal reference buffer can be disabled, allowing for the application of an external reference to VREFP. Figure 9.3.5 depicts a typical circuit for driving an external reference. The internal reference circuit can be powered down via the PD\_REFBUF bit in the CONFIG3 register. In scenarios where multiple chips are





cascaded, the internal reference of one chip can be shared by powering it down on the others. By default, upon wake-up, the chip operates using an external reference.





### **Digital decimation filter**

The digital filter receives the modulator output and decimates the data stream. By adjusting the filtering parameters, a trade-off can be made between resolution and data rate: more filtering yields higher resolution, whereas less filtering allows for a higher data rate. Higher data rates are typically employed in EEG applications for AC lead-off detection. The digital filter on each channel comprises a third-order sinc filter. The decimation ratio of the sinc filter can be adjusted via the DR bits in the CONFIG1 register. This setting is a global one affecting all channels, hence all channels in the chip operate at the same data rate. The sinc filter is a third-order low-pass filter with a variable decimation rate. Data enters the filter at the rate of  $f_{MOD}$  from the modulator, undergoes high-frequency noise filtering, and is then decimated into parallel data at the rate of fDR. The Z-domain transfer function of the sinc filter (with N as the decimation factor) is as follows:

$$|H(z)| = \left|\frac{1-Z^{-N}}{1-Z^{-1}}\right|^{3}$$

Figure 9.3.6/7 shows the transmission characteristics of the filter, with normalized frequency on the horizontal axis and gain (dB) on the vertical axis.



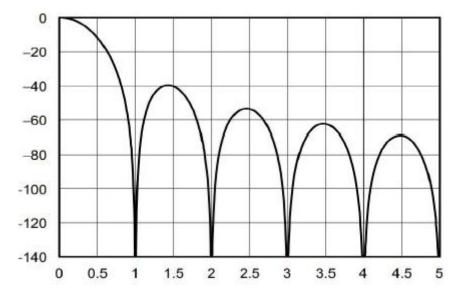
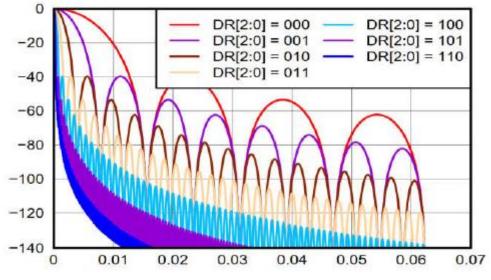
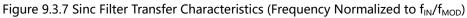


Figure 9.3.6 Sinc transmission characteristics (frequency normalized by  $f_{IN}/f_{DR}$ )





#### Clock

The CBM24AD99Q offers both internal and external clocking methods. The internal clock is suitable for low-power, battery-operated systems, with the oscillator factory-calibrated at room temperature for accuracy. Clock selection is governed by the CLKSEL pin and the CLK\_EN register bit. The CLKSEL pin determines whether the internal or external clock is used. The CLK\_EN bit in the CONFIG1 register enables or disables the oscillator clock to be output on the CLK pin. A truth table for these two controls is provided in Table 9.3.2.



### Table 9.3.2 Truth Table for CLKSEL Pin and CLK\_EN Bit

CLKSEL PIN	CONFIG1.CLK_EN BIT	CLOCK SOURCE	CLK PIN STATUS
0	x	External clock	Input: external clock
1	0	Internal clock oscillator	Tri-state
1	1	Internal clock oscillator	Output: internal clock oscillator

#### 9.3.8 General-Purpose Input/Output Interface

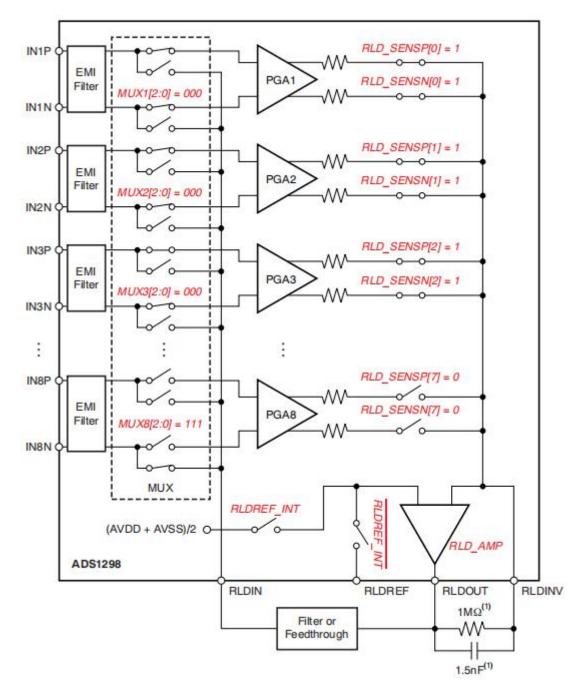
The CBM24AD99Q features four general-purpose digital I/O (GPIO) pins available during normal operation modes. These GPIO pins can be individually configured as inputs or outputs via the GPIOC bit registers. The GPIO level is controlled by the GPIOD bits in the GPIO register. Reading the GPIOD bits returns the logical level of the pin, regardless of whether they are programmed as inputs or outputs. Writing to the GPIOD bits is ineffective when the GPIO pins are configured as inputs. When set as outputs, writing to the GPIOD bits sets the GPIO output value.

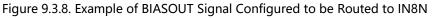
#### 9.3.9 Bias (BIAS) Drive Circuit

Employing a bias (BIAS) drive circuit to stimulate the body helps counteract common-mode interference in EEG systems caused by power lines and other sources, including fluorescent lighting. Figure 9.3.8 illustrates an example of a bias circuit connection. The reference voltage for the bias drive can be internally generated [(AVDD + AVSS)/2] or externally supplied via a resistor divider network. Selection of the bias loop's reference voltage, either internal or external, is defined by writing the appropriate value to the BIASREF\_INT bit in the CONFIG2 register. The BIAS\_SENSEP/N selects the corresponding channel to be connected to the BIASINV terminal of the bias circuit. Upon choosing the appropriate channel, feedback components, and closing the loop externally on the chip, a BIAS bias signal is outputted at the BIASOUT pin. This signal can be fed, after filtering or directly, into the BIASIN pin, as depicted in Figure 9.12. To route this BIASIN signal to the designated input P-side/N-side electrode, the MUX bits in the respective channel setting register must be set to "110" / "111".



#### OPERATION INSTRUCTION





The bias drive functionality can be disabled using the PD\_BIAS bit in the CONFIG3 register. When multiple CBM24AD99Q chips are daisy-chained, the PD\_BIAS bit is used to disable all but one of the bias amplifiers. Figure 9.3.9 demonstrates the setup with multiple chips connected for the bias circuit.



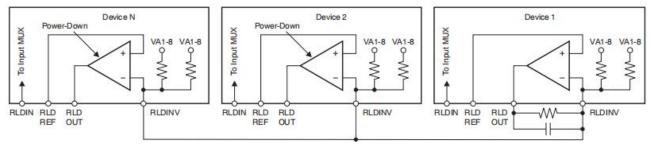


Figure 9.3.9 BIAS driver connections for multiple chips

Furthermore, the BIASOUT signal can be routed to a specific channel (not involved in the BIAS computation) for measurement purposes. Figure 3.9.10 illustrates the register settings required to route the BIASIN signal to Channel 8. The measurement is performed relative to the voltage on the BIASREF pin. If BIASREF is selected as internal, then BIASREF equals [(AVDD + AVSS)/2]. This feature can be utilized for debugging purposes during product development.

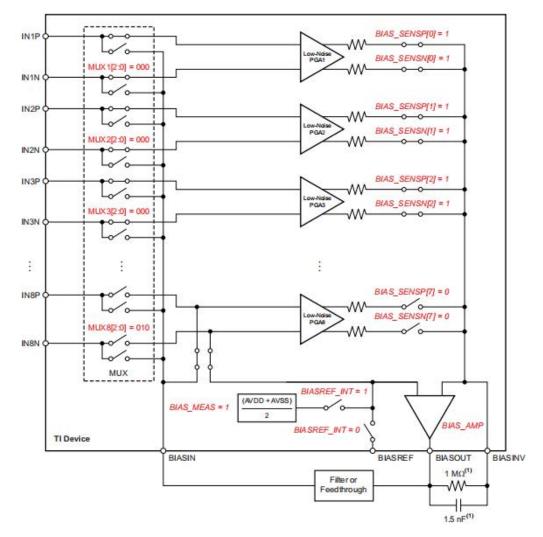


Figure 9.3.10. BIASOUT Signal Configured to be Read Back by Channel 8

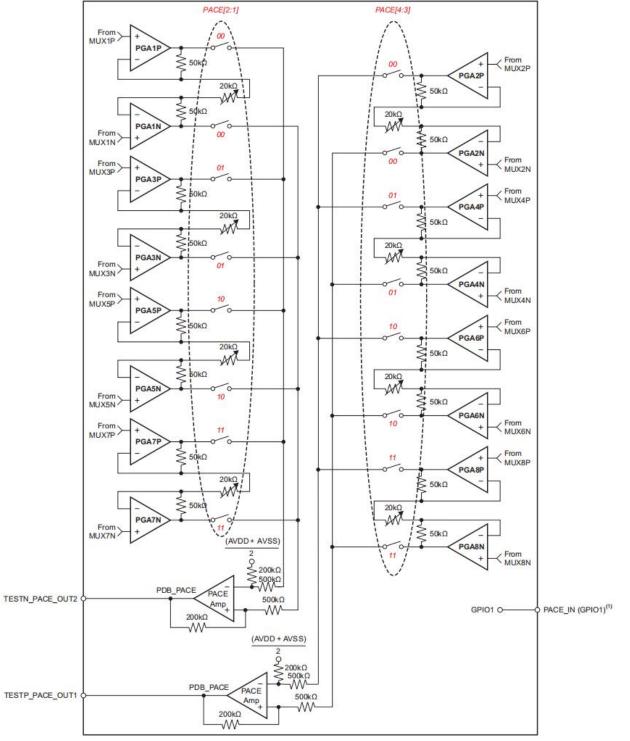


#### 9.3.10 Excitation reference (SRB1/2) drive circuit

In the CBM24AD99Q, besides the BIASOUT signal, which can serve as a reference for single-ended inputs, there are also two signals, SRB1 and SRB2, that can be references for single-ended inputs. Figure 9.3.11 shows the driver circuits for these two signals. The drive for SRB2 comes from odd channels, while the drive for SRB1 comes from even channels. The channel selection is controlled by the SRB2\_SEL and SRB1\_SEL register bits, respectively. See the MISC1 register definition for details. Note that there is a 0.4 attenuation when converting from differential to single-ended, hence the total gain equals ( $0.4 \times PGA_GAIN$ ). Unlike the BIASOUT signal, the SRB1/2 signal drives are already closed loop within the chip, thus they can be used directly without needing an external closed-loop circuit. For SRB1, it can only be routed to the negative end (N end) of all channels by the SRB1 bit in the MISC1 register, with the signal input from the positive end (P end), constituting a differential input with SRB1. As for SRB2, it can be routed to the positive end (P end) of the corresponding channel by the SRB2 bit in the CHnSET register of the respective channel, with the signal input from the negative end (N end), forming a differential input with SRB2. Note that signals input from the negative end will have their phase inverted after being sampled and output by the channel.



#### OPERATION INSTRUCTION



(1) GPIO1 can be used as the PACE\_IN signal.

Figure 9.3.11 Excitation and Reference (SRB1/2) Drive Circuit



#### Lead-off Detection (Electrode Disconnection Detection)

The contact impedance between electrodes and the human body may change over time or during usage, leading to disconnections, necessitating continuous monitoring of the electrode-to-body connection. The CBM24AD99Q features a lead-off detection module designed specifically for this purpose. Although referred to as lead-off detection, it essentially detects electrode detachment.Fundamentally, lead-off detection works by injecting an excitation current and measuring the voltage to ascertain the quality of electrode contact, as illustrated in Figure 9.3.12. The circuitry provides two distinct methods for determining the status of the electrodes, differing primarily in the frequency components of the excitation signal. The leads to be monitored can be selected using the LOFF SENSP and LOFF SENSN registers. The first method involves stimulating the lead with a DC signal. The DC stimulation signal can originate from external pull-up or pull-down resistors or from an internal current source or sink, as shown in Figure 9.3.12. One side of the channel is pulled up to the supply voltage, while the other is pulled down to ground. By setting the corresponding bits in the LOFF FLIP register, the pull-up and pull-down currents can be swapped. If a current source is used, the magnitude of the current can be set using the ILEAD OFF[1:0] bits in the LOFF register. Compared to a 10-M Ω pull-up or pull-down resistor, a current source offers a higher input impedance.

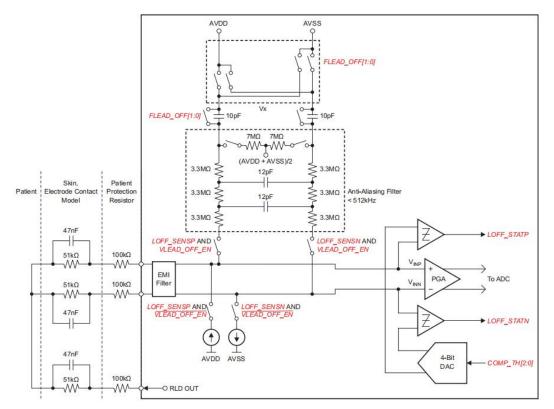


Figure 9.3.12. Lead-Off Detection



### OPERATION INSTRUCTION

The connection status of the leads can be monitored by reading the output code of the channel or by employing an on-chip comparator. Should the electrode become disconnected, the pull-up and pull-down resistances cause the channel to saturate. The comparator monitors the input voltage against a 3-bit DAC level, with the DAC level set by the COMP\_TH[2:0] bits in the LOFF register. The output of the comparator is stored in the LOFF\_STATP and LOFF\_STATN registers. This data forms part of the output data stream. (Refer to the Output Data section for more details.) If DC lead-off detection is not in use, the comparators can be deactivated by setting the PD\_LOFF\_COMP\_ bit in the CONFIG4 register.

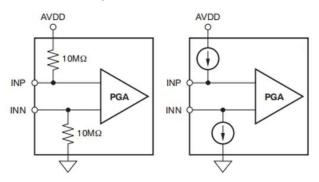


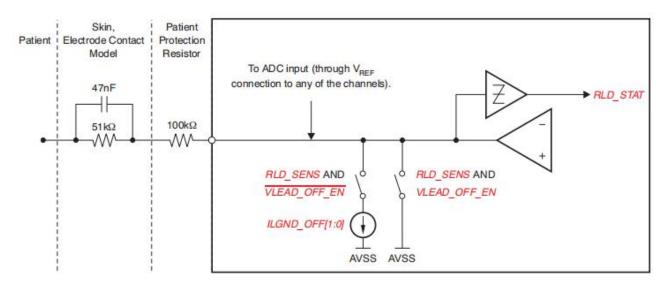
Figure 9.3.13 DC lead detachment detection options

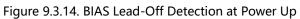
Another approach employs an in-band AC signal to stimulate the leads. The AC signal is generated by alternately providing a fixed-frequency current source at the input. The frequency can be selected using the FLEAD\_OFF[1:0] bits in the LOFF register (either 7.8 Hz or 31.2 Hz). This in-band excitation signal is captured through the channel and read at the output. The AC excitation introduces a frequency within the band of interest, which can be filtered and processed separately. The impedance of the electrodes can be calculated by measuring the output amplitude at the frequency of the excitation signal. For continuous lead-off detection, an out-of-band AC current can be applied externally to the input and digitally processed to determine electrode impedance.

#### 9.3.12 Bias Drive (BIAS) Lead-off Detection

During normal operation of the CBM24AD99Q, right leg drive (BIAS) lead-off detection cannot be utilized since the detection requires the disabling of the right leg drive amplifier. As depicted in Figure 9.3.14, the CBM24AD99Q employs a current source and a comparator to ascertain the connection state of the BIAS electrode. When the BIAS amplifier is powered on, the current source is inactive. The acceptable threshold for BIAS impedance can be determined by setting the reference level of the comparator, which is set in a manner identical to the threshold setting for other negative input signals, using the LOFF[7:5] bits. This threshold setting allows for the determination of the BIAS electrode's connectivity status.







## **Product Function Modes**

#### **Product Function Modes**

#### Start (START)

Initiating a conversion can be achieved by pulling the START pin high for at least 2 tCLK cycles, or by issuing a START command. When START is low and no START command has been transmitted, the chip does not assert the DRDY\_ signal (conversion is paused). When utilizing the START command to control conversions, maintain the START pin at a low level. The CFYA98 features two operational modes for controlling conversions: Continuous mode and Single-shot mode, which is selected by the SINGLE SHOT bit (bit 3 of the CONFIG4 register). In multi-chip configurations, the START pin serves to synchronize the chips. The settling time (tSETTLE) refers to the duration required for output data to become fully stable after the analog-to-digital conversion begins. Upon the assertion of START, DRDY is also pulled high. The subsequent falling edge of DRDY signifies that the data is ready. Figure 9.4.1 illustrates the timing diagram, while Table 9.4.1 lists the settling times for various data rates. The settling time depends on fCLK and the decimation rate (controlled by the DR[2:0] bits in the CONFIG1 register). Following the initial settling period, DRDY goes low, indicating that the data conversion is complete and will appear at the set data rate tDR. If data is not read back from DOUT before the next conversion is ready, DRDY goes high for 4 tCLK periods before returning low, signaling new data readiness.Note that when START remains high and there is a step change in the input signal, the filter requires 3×tDR to stabilize to the new value. Stable data is then ready at the fourth DRDY falling edge.



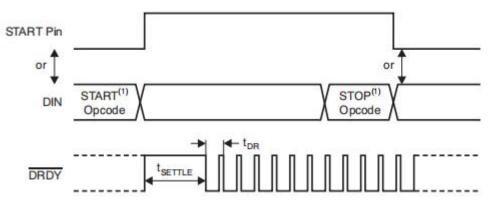


Figure 9.4.1 Stability time

#### Table 9.4.1 Establishment time for different data rates

DR[2:0]	Normal mode	Unit
000	521	t <sub>clK</sub>
001	1033	t <sub>clK</sub>
010	2057	t <sub>clk</sub>
011	4105	t <sub>clk</sub>
100	8201	t <sub>clk</sub>
101	16393	t <sub>CLK</sub>
110	32777	t <sub>CLK</sub>

### Reset (RESET\_)

There are two methods to reset the CBM24AD99Q: by pulling the RESET\_ pin low or by sending a RESET command. When using the RESET\_ pin, ensure compliance with the minimum pulse duration timing specification before pulling the pin back high. The RESET command takes effect on the eighth falling edge of SCLK after the command is issued. Following a reset, 18 tCLK cycles are required to initialize configuration registers to their default states and commence the conversion cycle. Note that an internal reset to the digital filter is automatically issued when the CONFIG1 register is set to a new value using the WREG command.9.4.3 Power-Down (PWDN\_) All on-chip circuits are shut off when the PWDN\_ pin is pulled low. To exit power-down mode, the PWDN\_ pin should be pulled high. After exiting power-down mode, the internal oscillator and reference require time to wake up. It is recommended to disable the external clock during power-down to conserve power.

#### **Data Acquisition**

(1) Data Ready (DRDY\_)



### OPERATION INSTRUCTION

DRDY\_ is an output signal that transitions from high to low to indicate new conversion data is ready. The CS\_ signal has no effect on the data ready signal. The behavior of DRDY\_ depends on whether the chip is in RDATAC mode, continuously outputting data, or using RDATA commands for on-demand data reads. When reading data with the RDATA command, the read operation can overlap with the next DRDY\_ without data corruption. The START pin or START command places the chip into either normal data capture mode or pulsed data capture mode.Figure 9.4.2 illustrates the relationship between DRDY\_, DOUT, and SCLK during data read operations. DOUT is latched on the rising edge of SCLK, and DRDY\_ is pulled high on the falling edge of SCLK. Note that DRDY\_ goes high on the first falling edge of SCLK, regardless of whether data is being read or commands are being sent via the DIN pin.

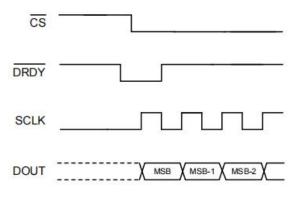


Figure 9.4.2 DRDY\_ with data retrieval (CS=0)

#### (2)Data Readout

Data readout can be accomplished through one of the following two methods:

1. RDATAC: The Continuous Data Read Command sets the chip into continuous read mode, where new data is automatically loaded into the output shift register upon completion of each data conversion without the need to send a command. For more detailed information, refer to the RDATAC: Continuous Data Read section.

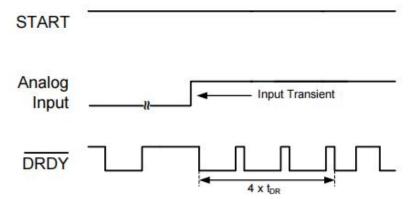
2. RDATA: The Data Read Command requires sending a command to the chip to load the latest data into the output shift register. For more detailed information, see the RDATA: Data Read section.Conversion data is read out by shifting data out on DOUT. The MSB of the data on DOUT is output on the first rising edge of SCLK. DRDY\_ returns high on the first falling edge of SCLK for the entire read operation. DIN should remain low for the duration of the read operation.The number of bits in the data output depends on the number of channels and the number of bits per channel. For an 8-channel CBM24AD99Q, the amount of data output is [24 status bits + (24 bits x 8 channels) = 216 bits]. The format of the 24 status bits is: (1100 + LOFF\_STATP +



LOFF\_STATN + bits [4:7] of the GPIO register). The data format for each channel is a two' s complement binary format with the MSB first. When channels are turned off using user register settings, the corresponding channel output is set to "0". However, the order of channel outputs remains unchanged. The CBM24AD99Q also offers multireadback functionality. By simply providing more SCLKs in RDATAC mode, data can be read multiple times, in which case the MSB data byte repeats after reading the last byte. For multireadback, the DAISY\_EN\_ bit in the CONFIG1 register must be set to "1".

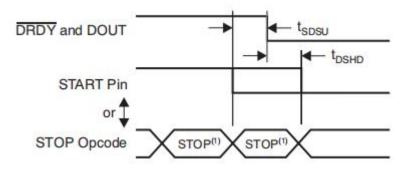
#### 9.4.5 Continuous Conversion Mode

Conversions begin when the START pin is pulled high or a START command is sent. As shown in Section 9.4.3, the DRDY\_ output goes high when the conversion starts and goes low when the data is ready. Conversions will continue indefinitely until the START pin goes low or a STOP command is sent. When the START pin is pulled low or a STOP command is issued, the currently ongoing conversion is allowed to complete. Figures 9.4.4 and Table 9.4.2 depict the timing of the START pin or the START and STOP commands to the DRDY\_ signal during data conversion. tSDSU indicates when the START pin should be pulled low or when the STOP command should be sent before the falling edge of DRDY\_ to halt further conversions. tDSHD indicates when the START pin should be pulled low or when the STOP command should be sent after the falling edge of DRDY\_ to complete the current conversion and halt further conversions. To keep the converter running continuously, the START pin can be kept high.When switching from Single-Shot mode to continuous conversion mode, pull the START signal low then high again, or send a STOP command followed by a START command. This conversion mode is suitable for applications requiring a fixed, continuous stream of conversions.



<sup>\*\*</sup>The START and STOP commands take effect on the 7th falling edge of SCLK. Figure 9.4.3 Continuous Conversion Mode





The START and STOP commands take effect on the seventh falling edge of the SCLK at the end of the command.

Figure 9.4.4 Start to DRDY timing

#### Table 9.4.2 Time series characteristics

		MIN	MAX	UNIT
t <sub>SDSU</sub>	START pin low or STOP opcode to DRDY setup time to halt further conversions	16		t <sub>CLK</sub>
t <sub>DSHD</sub>	START pin low or STOP opcode to complete current conversion	16		<b>t</b> CLK

### 9.4.6 Single-Shot Mode

Single-shot mode is enabled by setting the SINGLE\_SHOT bit in the CONFIG4 register to "1". In single-shot mode, the CBM24AD99Q performs a single conversion when the START pin is pulled high or a START command is issued. As illustrated in Figure 9.4.5, upon completion of the conversion, DRDY\_ goes low and halts further conversions. DRDY\_ remains low regardless of whether the conversion data is read or not. To initiate a new conversion, the START pin must be pulled low and then high again, or the START command must be resent. When transitioning from continuous conversion mode to single-shot mode, the START signal should be pulled low and then high again, or a STOP command should be issued before sending another START command.

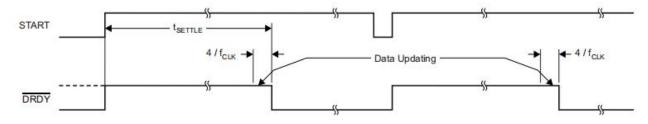


Figure 9.4.5 DRDY\_ No Data Recovery in SingLE-SHOT Mode

This conversion mode is tailored for applications that require non-standard or non-continuous data rates. Issuing a START command or toggling the START pin high resets the digital filter, effectively quartering the data rate. This mode imposes a heavier load on the host processor, as it must toggle the START pin or issue START commands to initiate new conversion cycles.

### 9.5 Programming



## 9.5.1 Data Format

The chip represents 24-bit data in two's complement format. The size of a least significant bit (LSB) in terms of voltage is calculated using the following formula:

1 LSB = (2 ×  $V_{REF}$  / Gain) / 2<sup>24</sup> = +FS / 2<sup>23</sup>

A full-scale positive input results in an output code of 7FFFFFh, whereas a full-scale negative input yields an output code of 800000h. For signals exceeding the full-scale range, the output clips at these codes. The table below summarizes the ideal output codes for various input signals.

INPUT SIGNAL, V <sub>IN</sub> (INxP – INxN)	IDEAL OUTPUT CODE <sup>(2)</sup>
≥ V <sub>REF</sub>	7FFFFFh
V <sub>REF</sub> / (2 <sup>23</sup> - 1)	000001h
0	000000h
-V <sub>REF</sub> / (2 <sup>23</sup> - 1)	FFFFFh
$\leq -V_{\text{REF}} (2^{23} / (2^{23} - 1))$	800000h

## Table 9.5.1 Ideal Output Code and Input Signal

## 9.5.2 SPI Interface

The SPI-compatible serial interface of the CBM24AD99Q is composed of four signals: CS\_, SCLK, DIN, and DOUT, which are used for reading conversion data, reading and writing to registers, and controlling the operation of the CBM24AD99Q. The data-ready output DRDY\_ acts as a status signal to indicate when data is ready, going low when new data becomes available.

## Chip Select (CS\_)

The CS\_ pin activates SPI communication. CS\_ must be low before data transfer and must remain low throughout the SPI communication cycle. When CS\_ is high, the DOUT pin enters a high-impedance state, causing reads and writes to the serial interface to be ignored and resetting the interface. DRDY\_ operates independently of CS\_; it still indicates a new conversion is complete and forces high in response to SCLK even when CS\_ is high. Setting CS\_ high stops SPI communication and resets the serial interface. Data conversion continues, and DRDY\_ can be monitored to check for readiness of new conversion results. A master device monitoring DRDY\_ can select the appropriate slave chip by pulling CS\_ low. After serial communication, wait for four or more tCLK cycles before pulling CS\_ high.

### Serial Clock (SCLK)

SCLK provides the clock for serial communication. SCLK is a Schmitt-trigger input, but a clean SCLK is advised to prevent glitches from inadvertently shifting data. Data is shifted into DIN on the falling edge of SCLK and out of DOUT on the rising edge.Ensure all SCLK clocks are sent to



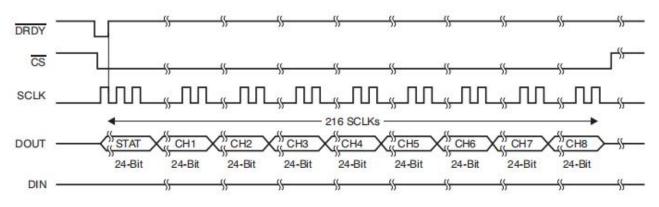
the chip when transmitting commands. Failure to do so may lead to an unknown state in the chip's SPI serial interface, requiring CS\_ to be pulled high for recovery.For a single chip, the minimum SCLK speed depends on the number of channels, resolution bits, and output data rate. For multiple cascaded chips, the SCLK frequency must ensure all channels' data can be read within the data-ready intervals. Data acquisition is accomplished by placing the chip in RDATAC mode or issuing RDATA commands.

#### Data Input (DIN)

DIN, along with SCLK, is used to send data to the chip. Data on DIN is shifted into the chip on the falling edge of SCLK.Communication with the chip is inherently full-duplex. The chip monitors incoming commands even while data is shifting out. When sending commands, data from the output shift register is shifted out. Therefore, ensure anything sent on DIN during data output is valid. Send a NOP command on DIN when not sending commands to the chip during data reads.

#### Data Output (DOUT)

DOUT, in conjunction with SCLK, is used to read conversion and register data from the chip. Data is output on the rising edge of SCLK, with the MSB first. DOUT enters a high-impedance state when CS\_ is high. Figure 9.5.1 illustrates the CBM24AD99Q data output protocol.



#### Figure 9.5.1 SPI Bus Data Output

The SPI command definitions for the CBM24AD99Q provide flexible configuration control. The operations for command control and configuring the chip are listed in Table 9.5.2. Except for register read and write operations, which require data appended to the second command byte, all other commands are standalone. CS\_ can be released high or kept low between commands, but it must remain low throughout the entire command operation (especially for multi-byte commands). System commands and RDATA commands are decoded by the chip on the falling edge of the seventh SCLK. Register read/write commands are decoded on the falling edge of the seventh SCLK. When pulling CS\_ high after issuing a command, make sure to follow the SPI timing requirements. Table 10. Command Definitions



COMMAND	DESCRIPTION	FIRST BYTE	SECOND BYTE
SYSTEM COMM	ANDS		
WAKEUP	Wakeup from standby mode	0000 0010 (02h)	81 <u></u> 3
STANDBY	Enter standby mode	0000 0100 (04h)	
RESET	Reset the device	0000 0110 (06h)	( <del></del>
START	Start/restart (synchronize) conversions	0000 1000 (08h)	(1-1)
STOP	Stop conversion	0000 1010 (0Ah)	32 <u></u> 3
DATA READ CO	MMANDS	14	8
RDATAC	Enable Read Data Continuous mode. This mode is the default mode at power up. <sup>(1)</sup>	0001 0000 (10h)	
SDATAC	Stop Read Data Continuously mode	0001 0001 (11h)	-
RDATA	Read data by command; supports multiple read back.	0001 0010 (12h)	32 <u></u> 3
REGISTER REAL	COMMANDS	- 	
RREG	Read n nnnn registers starting at address r mr	001r mm (2xh) <sup>(2)</sup>	000 <i>n nnnn</i> <sup>(2)</sup>
WREG	Write n nnnn registers starting at address r mr	010r mm (4xh) <sup>(2)</sup>	000n nnnn <sup>(2)</sup>

(1) In RDATAC mode, the RREG command will be ignored.

(2) n nnnn represents the number of registers to read or write minus one. For instance, to read or write three registers, set n nnnn to 0 (binary 0010). r rrrr denotes the starting register address for the read or write command.

#### (1) Sending Multi-Byte Commands

The CBM24AD99Q serial interface decodes commands byte by byte, requiring 4 tCLK cycles for decoding and execution. Therefore, when sending multi-byte commands (such as RREG or WREG), the end of one byte (or command) must be separated from the end of the next byte (or command) by 4 tCLK cycles. Assuming CLK is 2.048 MHz, then tSDECODE (4tCLK) is 1.96  $\mu$ s. When SCLK is 16MHz, one byte can be transmitted within 500ns (0.5  $\mu$ s). This byte transmission time does not meet the tSDECODE specification; therefore, a delay must be inserted so that the end of the second byte arrives after 1.46  $\mu$ s. If SCLK is 4 MHz, then one byte is transmitted within 2  $\mu$ s. Since this transmission time exceeds the tSDECODE specification, the processor can send subsequent bytes without delay.

#### (2) WAKEUP: Exit Standby Mode

The WAKEUP command exits the low-power standby mode. This command has no SCLK rate limit and can be issued at any time. Any subsequent commands must be sent after a delay of 4 tCLK cycles.

#### (3) STANDBY: Enter Standby Mode

The STANDBY command enters the low-power standby mode. All parts of the circuit except for the reference section are shut down. This command has no SCLK rate limit and can be issued at any time. After the chip enters standby mode, do not send any other commands except for the wakeup command.

#### (4) **RESET:** Reset Registers to Default Values



The RESET command resets the digital filter period and sets all registers back to their default values. This command has no SCLK rate limit and can be issued at any time. Executing the RESET command requires 18 tCLK cycles; avoid sending any commands during this period.

#### (5) START: Start Conversion

The START command initiates data conversion. The START pin needs to be pulled low to control the conversion through the command. If a conversion is already in progress, this command is invalid. The STOP command stops the conversion. If a START command is immediately followed by a STOP command, there must be a delay of 4 tCLK cycles between them. When sending the START command to the chip, keep the START pin low until the STOP command is issued. This command has no SCLK rate limit and can be issued at any time.

#### (6) STOP: Stop Conversion

The STOP command halts the conversion. Pull the START pin low to control the conversion via the command. When the STOP command is issued, the ongoing conversion completes and further conversions are stopped. If the conversion has already been stopped, this command is invalid. This command has no SCLK rate limit and can be issued at any time. (7) RDATAC: Continuous Read Data The RDATAC command initiates the output of conversion data on each DRDY without the need for subsequent read data commands. This mode places the conversion data in the output register, where it can be directly shifted out. The continuous read data mode is the default mode for the chip, which defaults to this mode upon power-up. The RDATAC mode is canceled by a stop read data continuously command. If the chip is in RDATAC mode, a SDATAC command must first be issued before any other commands can be sent to the chip. This command has no SCLK rate limit; however, subsequent data read SCLK or SDATAC commands should wait for at least 4 tCLK cycles before completion (see the section on sending multi-byte commands). The timing for RDATAC is shown in Figure 9.5.2, with a prohibited area of 4 tCLK cycles around the DRDY pulse where this command cannot be issued. To read data from the chip after issuing the RDATAC command, ensure that the START pin is high or issue a START command.



CBM24AD99Q

OPERATION INSTRUCTION

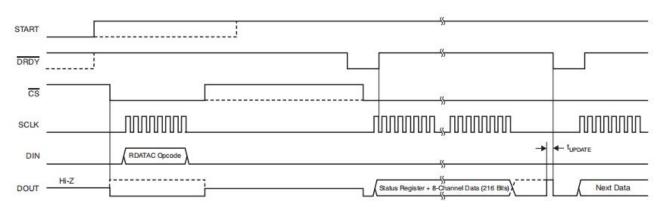
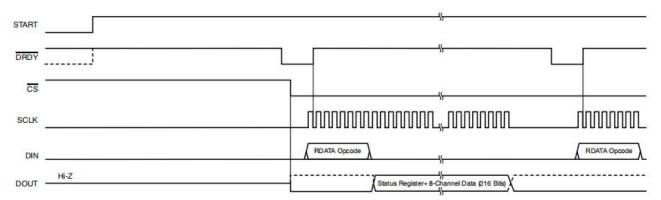


Figure 9.5.2 Usage of RDATAC command

(8) SDATAC: Stop Reading Data Continuously The SDATAC command cancels the continuous read data mode. This command has no SCLK rate limit, but the next command must wait for 4 tCLK cycles before completion. (9) RDATA: Read Data When not in continuous read data mode, the RDATA command loads the latest data into the output shift register. Issue this command after DRDY\_ goes low to read the conversion result. This command has no SCLK rate limit, and no waiting time is required for subsequent commands or data read SCLKs. To read data from the chip after issuing the RDATA command, ensure that the START pin is high or issue a START command. When using the RDATA command to read data, the read operation can overlap with the next DRDY\_ without corrupting the data. Figure 9.5.3 illustrates the usage of the RDATA command.



#### Figure 9.5.3 Usage of RDATA command

(10) RREG: Read Data from Register This command reads data from the register. The register read command is a two-byte command followed by the output of register data. The first byte contains the command and the register address. The second command byte specifies the number of registers to read, minus one. First command byte: 001r rrrr, where r rrrr is the starting register address. Second command byte: 000n nnnn, where n nnnn is the number of registers to read, minus one. The MSB of the first register is output on the 17th rising edge of SCLK, as shown in



Figure 9.5.4. When the chip is in continuous read data mode, an SDATAC command must be issued before the RREG command can be sent. The RREG command can be issued at any time. However, since this command is a multi-byte command, it has an SCLK rate limit due to the need to meet the tSDECODE timing for SCLK issuance. Note that CS\_ must remain low throughout the entire command duration.

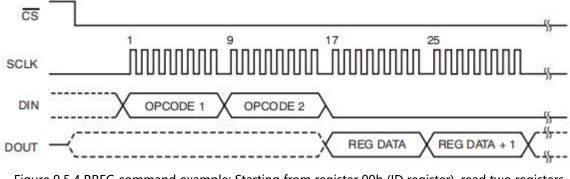


Figure 9.5.4 RREG command example: Starting from register 00h (ID register), read two registers (BYTE1=00100000, BYTE 2)=00000001)

(11) WREG: Write Data to Register This command writes data to the register. The register write command is a two-byte command followed by the input of register data. The first byte contains the command and the register address. The second command byte specifies the number of registers to write, minus one. First command byte: 010r rrrr, where r rrrr is the starting register address. Second command byte: 000n nnnn, where n nnnn is the number of registers to write, minus one. Following the command bytes is the register data (MSB-first format), as shown in Figure 9.5.5. The WREG command can be issued at any time; however, since this command is a multi-byte command, it has an SCLK rate limit due to the need to meet the tSDECODE timing for SCLK issuance. Note that CS\_ must remain low throughout the entire command duration.

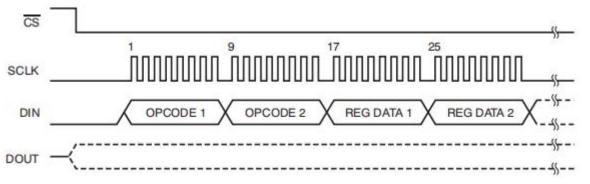


Figure 9.5.5 Example of WREG command: Starting from 00h (ID register), write two registers (BYTE 1=0100 0000, BYTE2=000000 1)





# **Register Definition**

#### **Register Definition**

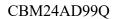
#### Table 9.6.1 illustrates the various CBM24AD99Q registers.

#### Table 9.6.1 Register Allocation

		DEFAULT				REGIST	ER BITS					
ADDRESS	REGISTER	SETTING	7	6	5	4	3	2	1	0		
Read Only ID	Registers		63 19	64 6	i e			0				
00h	ID	xxh	10 1-	REV_ID[2:0]		1	DEV_	ID[1:0]	NU_C	H[1:0]		
Global Setting	s Across Channel	s				•						
01h	CONFIG1	96h	1	1 DAISY_EN CLK_EN 1					DR[2:0]			
02h	CONFIG2	C0h	1	1	0	INT_CAL	0	CAL_AMP0	CAL_FF	REQ[1:0]		
03h	CONFIG3	60h	PD_REF BUF	1	1	BIAS_MEAS	BIASREF_INT	PD_BIAS	BIAS_LOFF_ SENS	BIAS_STAT		
04h	LOFF	00h		COMP_TH[2:0] 0				OFF[1:0]	FLEAD	OFF[1:0]		
Channel-Spec	ific Settings					•						
05h	CH1SET	61h	PD1		GAIN 1[2:0]		SRB2		MUX1[2:0]			
06h	CH2SET	61h	PD2	GAIN2[2:0]			SRB2	MUX2[2:0]				
07h	CH3SET	61h	PD3	PD3 GAIN3[2:0]				MUX3[2:0]				
08h	CH4SET	61h	PD4	PD4 GAIN4[2:0]					MUX4[2:0]			
09h	CH5SET (9	61h	PD5	PD5 GAIN 5[2:0]					MUX5[2:0]			
QAh	CH6SET (1)	61h	PD6	PD6 GAIN6[2:0]				MUX6[2:0]				
0Bh	CH7SET (2)	61h	PD7		GAIN 7[2:0]		SRB2	MUX7[2:0]				
0Ch	CH8SET (2)	61h	PD8	0	GAIN8[2:0]		SRB2	MUX8[2:0]				
0Dh	BIAS_SENSP	00h	BIASP8 <sup>(2)</sup>	BIASP7 <sup>(2)</sup>	BIASP6 <sup>(1)</sup>	BIASP5(1)	BIASP4	BIASP3	BIASP2	BIASP1		
0Eh	BIAS_SENSN	00h	BIASN8 <sup>(2)</sup>	BIASN7 <sup>(2)</sup>	BIASN6(1)	BIASN5(1)	BIASN4	BIASN3	BIASN2	BIASN1		
0Fh	LOFF_SENSP	00h	LOFFP8 <sup>(2)</sup>	LOFFP7 <sup>(2)</sup>	LOFFP6 <sup>(1)</sup>	LOFFP5 <sup>(1)</sup>	LOFFP4	LOFFP3	LOFFP2	LOFF P1		
10h	LOFF_SENSN	00h	LOFFM8 <sup>(2)</sup>	LOFFM7 <sup>(2)</sup>	LOFFM6 <sup>(1)</sup>	LOFF M5 <sup>(1)</sup>	LOFFM4	LOFFM3	LOFF M2	LOFFM1		
11h	LOFF_FLIP	00h	LOFF_FLIP8(2)	LOFF_FLIP7(2)	LOFF_FLIP6(1)	LOFF_FLIP5(1)	LOFF_FLIP4	LOFF_FLIP3	LOFF_FLIP2	LOFF_FLIP1		
Lead-Off State	us Registers (Read	-Only Registe	ers)				and a second second					
12h	LOFF_STATP	00h	IN8P_OFF	IN7P_OFF	IN6P_OFF	IN5P_OFF	IN4P_OFF	IN3P_OFF	IN2P_OFF	IN1P_OFF		
13h	LOFF_STATN	00h	IN8M_OFF	IN7M_OFF	IN6M_OFF	IN5M_OFF	IN4M_OFF	IN3M_OFF	IN2M_OFF	IN1M_OFF		
GPIO and OT	HER Registers	· · · ·		•	Cutta		•	v		i boars		
14h	GPIO	0Fh		GPIOD[4:1]				GPIOC[4:1]				
15h	MISC1	00h	0	0	SRB1	0	0	0	0	0		
16h	MISC2	00h	0	0	0	0	0	0	0	0		
17h	CONFIG4	00h	0	0	o	0	SINGLE_ SHOT	o	PD_LOFF_ COMP	0		

(1) Registers or bits are only available in the CBM24AD99Q-6 and CBM24AD99Q. In the CBM24AD99Q-4, the register bits are set to 0h or 00h.

(2) Registers or bits are only available in the CBM24AD99Q. In both the CBM24AD99Q-4 and CBM24AD99Q-6, the register bits are set to 0h.





#### 9.6.1 Register Descriptions

The read-only ID control register is programmed during device manufacture to indicate device characteristics.

#### 9.6.1.1 ID: ID Control Register (address = 00h) (reset = xxh)

7	6	5	4	3	2	1	0
	DEV_ID[7:5]		1	0	DEV_ID[2:0]		
	R-x		R-2h R-x				

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

#### Table 9.6.2. ID Control Register Field Descriptions

Bit	Field	Туре	Reset	Description
7:5	DEV_ID[7:5]	R	xh	Device ID These bits indicate the device family. 000 = Reserved 011 = Reserved 100 = ADS129x device family 101 = Reserved 110 = ADS129xR device family 111 = Reserved
4:3	RESERVED	R	2h	Reserved Always read back 2h
2:0	DEV_ID[2:0]	R	xh	Channel ID These bits indicates number of channels. 000 = 4-channel ADS1294 or ADS1294R 001 = 6-channel ADS1296 or ADS1296R 010 = 8-channel ADS1298 or ADS1298R 011 = Reserved 111 = Reserved

### 9.6.2 CONFIG1: Configuration Register 1 (address = 01h) (reset = 06h)

This register is configured with DAISY-EN\_ bit, clock, and data rate.

7	6	5	4	3	2	1	0
HR	DAISY_EN	CLK_EN	0	0		DR[2:0]	
R/W-0h	R/W-0h	R/W-0h	R/W-0h			R/W-6h	



Table 963	Configuration	Register 1	Field	Description
Table 9.0.5	Configuration	Register i	Field	Description

Bit	Field	Туре	Reset	Description
7	Reserved	R/W	1h	Reserved Always write 1h
6	DAISY_EN	R/W	Oh	Daisy-chain or multiple readback mode This bit determines which mode is enabled. 0 : Daisy-chain mode 1 : Multiple readback mode
5	CLK_EN	R/W	Oh	CLK connection <sup>(1)</sup> This bit determines if the internal oscillator signal is connected to the CLK pin when the CLKSEL pin = 1. 0 : Oscillator clock output disabled 1 : Oscillator clock output enabled
4:3	Reserved	R/W	2h	Reserved Always write 2h
2:0	DR[2:0]	R/W	6h	Output data rate           These bits determine the output data rate of the device. $f_{MOD} = f_{CLK} / 2$ .           000 : $f_{MOD} / 64$ (16 kSPS)           001 : $f_{MOD} / 128$ (8 kSPS)           010 : $f_{MOD} / 256$ (4 kSPS)           011 : $f_{MOD} / 512$ (2 kSPS)           100 : $f_{MOD} / 1024$ (1 kSPS)           101 : $f_{MOD} / 2048$ (500 SPS)           110 : $f_{MOD} / 4096$ (250 SPS)           111 : Reserved (do not use)

(1)Additional power is consumed when driving external devices.

#### 9.6.3 PROFIG2: Configuration Register 2 (Address=02h) (Reset=40h)

This register is mainly used to configure the generation of test signals.

#### Figure 9.6.3 PROFIG2: Configuration Register 2

7	6	5	4	3	2	1 0
1	1	0	INT_CAL	0	CAL_AMP	CAL_FREQ[1:0]
R/W-1h	R/W-1h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

#### Table 9.6.4 Configuration Register 2 Field Description

Bit	Field	Туре	Reset	Description
7:5	Reserved	R/W	6h	Reserved Always write 6h
4	INT_CAL	R/W	Oh	TEST source This bit determines the source for the test signal. 0 : Test signals are driven externally 1 : Test signals are generated internally
3	Reserved	R/W	0h	Reserved Always write 0h
2	CAL_AMP	R/W	Oh	Test signal amplitude These bits determine the calibration signal amplitude. 0 : 1 × -(VREFP - VREFN) / 2400 1 : 2 × -(VREFP - VREFN) / 2400
1:0	CAL_FREQ[1:0]	R/W	Oh	Test signal frequencyThese bits determine the calibration signal frequency.00 : Pulsed at $f_{CLK} / 2^{21}$ 01 : Pulsed at $f_{CLK} / 2^{20}$ 10 : Do not use11 : At dc



#### 9.6.4 PROFIG3: Configuration Register 3 (Address=03h) (Reset=40h)

This register is configured for internal or external reference and BIAS operations.

#### Figure 9.6.4 PROFIG3: Configuration Register 3

7	6	5	4	3	2	1	0
PD_REFBUF	1	1	BIAS_MEAS	BIASREF_INT	PD_BIAS	BIAS_LOFF_ SENS	BIAS_STAT
R/W-0h	R/W-1h	R/W-1h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R-0h

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

#### Table 9.6.5 Configuration Register 3 Field Description

Bit	Field	Туре	Reset	Description			
7	PD_REFBUF	R/W	Oh	Power-down reference buffer This bit determines the power-down reference buffer state. 0 : Power-down internal reference buffer 1 : Enable internal reference buffer			
6:5	Reserved	R/W	3h	Reserved Always write 3h.			
4	BIAS_MEAS	R/W	Oh	BIAS measurement This bit enables BIAS measurement. The BIAS signal ma measured with any channel. 0 : Open 1 : BIAS_IN signal is routed to the channel that has the MUX_Setting 010 (V <sub>REF</sub> )			
3	BIASREF_INT	R/W	Oh	BIASREF signal This bit determines the BIASREF signal source. 0 : BIASREF signal fed externally 1 : BIASREF signal (AVDD + AVSS) / 2 generated internally			
2	PD_BIAS	R/W	Oh	BIAS buffer power This bit determines the BIAS buffer power state. 0 : BIAS buffer is powered down 1 : BIAS buffer is enabled			
1	BIAS_LOFF_SENS	R/W	Oh	BIAS sense function This bit enables the BIAS sense function. 0 : BIAS sense is disabled 1 : BIAS sense is enabled			
0	BIAS_STAT	R	Oh	BIAS lead-off status This bit determines the BIAS status. 0 : BIAS is connected 1 : BIAS is not connected			

#### 9.65 LOFF: Lead-Off Control Register (address = 04h) (reset = 00h)

The lead-off control register configures the lead-off detection operation.

#### Figure 9.6.5 LOFF: Lead-Off Control Register

7	6	5	4	3	2	1	0
	COMP_TH2[2:0] 0		0	ILEAD_OF	F[1:0]	FLEAD_OFF[1:0]	
·	R/W-0h		R/W-0h	R/W-0h R/W-0h		R/W	-0h



Bit	Field	Туре	Reset	Description
7:5	COMP_TH[2:0]	R/W	0h	Lead-off comparator threshold Comparator positive side 000 : 95% 001 : 92.5% 010 : 90% 011 : 87.5% 100 : 85% 101 : 80% 110 : 75% 111 : 70% Comparator negative side 000 : 5% 001 : 7.5% 010 : 10% 011 : 12.5% 100 : 15% 101 : 20% 111 : 30%
4	Reserved	R/W	0h	Reserved Always write 0h.
3:2	ILEAD_OFF[1:0]	RW	0h	Lead-off current magnitude These bits determine the magnitude of current for the current lead-off mode. 00 : 6 nA 01 : 24 nA 10 : 6 µA 11 : 24 µA
1:0	FLEAD_OFF[1:0]	R/W	0h	<b>Lead-off frequency</b> These bits determine the frequency of lead-off detect for each channel. 00 : DC lead-off detection 01 : AC lead-off detection at 7.8 Hz ( $f_{CLK} / 2^{18}$ ) 10 : AC lead-off detection at 31.2 Hz ( $f_{CLK} / 2^{16}$ ) 11 : AC lead-off detection at $f_{DR} / 4$

#### Table 9.6.6. Lead-Off Control Register Field Descriptions

#### 9.6.6 CHnSET: Individual Channel Settings (n = 1 to 8) (address = 05h to 0Ch) (reset = 00h)

The CH[1:8]SET control register configures the power mode, PGA gain, and multiplexer settings channels. See the Input Multiplexer section for details. CH[2:8]SET are similar to CH1SET, corresponding to the respective channels.

#### Figure 9.6.6. CHnSET: Individual Channel Settings Register

7	6	5	4	3	2	1	0
PDn		GAINn[2:0]		SRB2		MUXn[2:0]	110
R/W-0h		R/W-6h		R/W-0h		R/W-0h	



Bit	Field	Туре	Reset	Description
7	PDn	R/W	0h	Power-down         This bit determines the channel power mode for the corresponding channel.         0 : Normal operation         1 : Channel power-down.         When powering down a channel, TI recommends that the channel be set to input short by setting the appropriate MUXn[2:0] = 001 of the CHnSET register.
6:4	GAIN <i>n</i> [2:0]	R/W	6h	PGA gain           These bits determine the PGA gain setting.           000 : 1           001 : 2           010 : 4           010 : 6           100 : 8           101 : 12           110 : 24           111 : Do not use
3	SRB2	R/W	Oh	SRB2 connection This bit determines the SRB2 connection for the corresponding channel. 0 : Open 1 : Closed
2:0	MUX <i>n</i> [2:0]	R/W	1h	Channel input These bits determine the channel input selection. 000 : Normal electrode input 001 : Input shorted (for offset or noise measurements) 010 : Used in conjunction with BIAS_MEAS bit for BIAS measurements. 011 : MVDD for supply measurement 100 : Temperature sensor 101 : Test signal 110 : BIAS_DRP (positive electrode is the driver) 111 : BIAS_DRN (negative electrode is the driver)

#### Table 9.6.7. Individual Channel Settings (n = 1 to 8) Field Descriptions

#### 9.6.7 BIAS\_SENSP: BIAS Positive Signal Derivation Register (address = 0Dh) (reset = 00h)

This register controls the selection of the positive signals from each channel for right leg drive (BIAS) derivation.

#### Figure 9.6.7. BIAS\_SENSP: BIAS Positive Signal Derivation Register

7	6	5	4	3	2	1	0
BIASP8	BIASP7	BIASP6	BIASP5	BIASP4	BIASP3	BIASP2	BIASP1
R/W-0h							



Bit	Field	Туре	Reset	Description
7	BIASP8	R/W	Oh	IN8P to BIAS Route channel 8 positive signal into BIAS derivation 0 : Disabled 1 : Enabled
6	BIASP7	R/W	Oh	IN7P to BIAS Route channel 7 positive signal into BIAS derivation 0 : Disabled 1 : Enabled
5	BIASP6	R/W	Oh	IN6P to BIAS Route channel 6 positive signal into BIAS derivation 0 : Disabled 1 : Enabled
4	BIASP5	R/W	Oh	IN5P to BIAS Route channel 5 positive signal into BIAS derivation 0 : Disabled 1 : Enabled
3	BIASP4	R/W	Oh	IN4P to BIAS Route channel 4 positive signal into BIAS derivation 0 : Disabled 1 : Enabled
2	BIASP3	R/W	Oh	IN3P to BIAS Route channel 3 positive signal into BIAS derivation 0 : Disabled 1 : Enabled
1	BIASP2	R/W	Oh	IN2P to BIAS Route channel 2 positive signal into BIAS channel 0 : Disabled 1 : Enabled
0	BIASP1	R/W	Oh	IN1P to BIAS Route channel 1 positive signal into BIAS channel 0 : Disabled 1 : Enabled

#### Table 9.6.8. BIAS Positive Signal Derivation Field Descriptions

#### 9.6.8 BIAS\_SENSN: BIAS Negative Signal Derivation Register (address = 0Eh) (reset = 00h)

This register controls the selection of the negative signals from each channel for right leg drive derivation. See the Right Leg Drive (BIAS) DC Bias Circuit section for details.

#### Figure 9.6.8. BIAS\_SENSN: BIAS Negative Signal Derivation Register

7	6	5	4	3	2	1	0
BIASN8	BIASN7	BIASN6	BIASN5	BIASN4	BIASN3	BIASN2	BIASN1
R/W-0h							



Bit	Field	Туре	Reset	Description
7	BIASN8	R/W	Oh	IN8N to BIAS Route channel 8 negative signal into BIAS derivation 0 : Disabled 1 : Enabled
6	BIASN7	R/W	Oh	IN7N to BIAS Route channel 7 negative signal into BIAS derivation 0 : Disabled 1 : Enabled
5	BIASN6	R/W	Oh	IN6N to BIAS Route channel 6 negative signal into BIAS derivation 0 : Disabled 1 : Enabled
4	BIASN5	R/W	Oh	IN5N to BIAS Route channel 5 negative signal into BIAS derivation 0 : Disabled 1 : Enabled
3	BIASN4	R/W	Oh	IN4N to BIAS Route channel 4 negative signal into BIAS derivation 0 : Disabled 1 : Enabled
2	BIASN3	R/W	Oh	IN3N to BIAS Route channel 3 negative signal into BIAS derivation 0 : Disabled 1 : Enabled
1	BIASN2	R/W	Oh	IN2N to BIAS Route channel 2 negative signal into BIAS derivation 0 : Disabled 1 : Enabled
0	BIASN1	R/W	Oh	IN1N to BIAS Route channel 1 negative signal into BIAS derivation 0 : Disabled 1 : Enabled

#### Table 9.6.9. BIAS Negative Signal Derivation Field Descriptions

#### 9.6.9 LOFF\_SENSP: Positive Signal Lead-Off Detection Register (address = 0Fh) (reset = 00h)

This register selects the positive side from each channel for lead-off detection. See the Lead-Off Detection section for details. The LOFF\_STATP register bits are only valid if the corresponding LOFF\_SENSP bits are set to 1.

#### Figure 9.6.9. LOFF\_SENSP: Positive Signal Lead-Off Detection Register

7	6	5	4	3	2	1	0
LOFF8P	LOFF7P	LOFF6P	LOFF5P	LOFF4P	LOFF3P	LOFF2P	LOFF1P
R/W-0h							



Bit	Field	Туре	Reset	Description	
7	LOFF8P	R/W	Oh	IN8P lead off Enable lead-off detection on IN8P 0: Disabled 1: Enabled	
6	LOFF7P	R/W	Oh	IN7P lead off Enable lead-off detection on IN7P 0: Disabled 1: Enabled	
5	LOFF6P	R/W	Oh	IN6P lead off Enable lead-off detection on IN6P 0: Disabled 1: Enabled	
4	LOFF5P	R/W	Oh	IN5P lead off Enable lead-off detection on IN5P 0: Disabled 1: Enabled	
3	LOFF4P	R/W	Oh	IN4P lead off Enable lead-off detection on IN4P 0: Disabled 1: Enabled	
2	LOFF3P	R/W	Oh	1: Enabled IN3P lead off Enable lead-off detection on IN3P 0: Disabled 1: Enabled	
1	LOFF2P	R/W	Oh	IN2P lead off Enable lead-off detection on IN2P 0: Disabled 1: Enabled	
0	LOFF1P	R/W	Oh	IN1P lead off Enable lead-off detection on IN1P 0: Disabled 1: Enabled	

#### Table 9.6.10. Positive Signal Lead-Off Detection Field Descriptions

# 9.6.10 LOFF\_SENSN: Negative Signal Lead-Off Detection Register (address = 10h) (reset = 00h)

This register selects the negative side from each channel for lead-off detection. See the Lead-Off Detection section for details. The LOFF\_STATN register bits are only valid if the corresponding LOFF\_SENSN bits are set to 1.

#### Figure 9.6.10. LOFF\_SENSN: Negative Signal Lead-Off Detection Register

7	6	5	4	3	2	1	0
LOFF8N	LOFF7N	LOFF6N	LOFF5N	LOFF4N	LOFF3N	LOFF2N	LOFF1N
R/W-0h							



Bit	Field	Туре	Reset	Description	
7	LOFF8N	R/W	Oh	IN8N lead off Enable lead-off detection on IN8N 0: Disabled 1: Enabled	
6	LOFF7N	R/W	Oh	IN7N lead off Enable lead-off detection on IN7N 0: Disabled 1: Enabled	
5	LOFF6N	R/W	Oh	IN6N lead off Enable lead-off detection on IN6N 0: Disabled 1: Enabled	
4	LOFF5N	R/W	Oh	IN5N lead off Enable lead-off detection on IN5N 0: Disabled 1: Enabled	
3	LOFF4N	R/W	Oh	IN4N lead off Enable lead-off detectionn on IN4N 0: Disabled 1: Enabled	
2	LOFF3N	R/W	Oh	IN3N lead off Enable lead-off detectionion on IN3N 0: Disabled 1: Enabled	
1	LOFF2N	R/W	Oh	IN2N lead off Enable lead-off detectionction on IN2N 0: Disabled 1: Enabled	
0	LOFF1N	R/W	Oh	IN1N lead off Enable lead-off detectionction on IN1N 0: Disabled 1: Enabled	

#### Table 9.6.11. Negative Signal Lead-Off Detection Field Descriptions

### 9.6.11 LOFF\_FLIP: Lead-Off Flip Register (address = 11h) (reset = 00h)

This register controls the direction of the current used for lead-off derivation. See the Lead-Off Detection section for details.

#### Figure 9.6.11. LOFF\_FLIP: Lead-Off Flip Register

7	6	5	4	3	2	1	0
LOFF_FLIP8	LOFF_FLIP7	LOFF_FLIP6	LOFF_FLIP5	LOFF_FLIP4	LOFF_FLIP3	LOFF_FLIP2	LOFF_FLIP1
R/W-0h							



Table 9.6.12.	Lead-Off Flin	Register Field	Descriptions
		incgister riera	Descriptions

Bit	Field	Туре	Reset	Description			
7	LOFF_FLIP8	R/W	Oh	Channel 8 LOFF polarity flip Flip the pullup/pulldown polarity of the current source or resistor on channel 8 for lead-off derivation. 0: No Flip: IN8P is pulled to AVDD and IN8N pulled to AVSS 1: Flipped: IN8P is pulled to AVSS and IN8N pulled to AVDD			
6	LOFF_FLIP7	R/W	Oh	Channel 7 LOFF polarity flip Flip the pullup/pulldown polarity of the current source or resistor on channel 7 for lead-off derivation. 0: No Flip: IN7P is pulled to AVDD and IN7N pulled to AVSS 1: Flipped: IN7P is pulled to AVSS and IN7N pulled to AVDD			
5	LOFF_FLIP6	R/W	0h	1: Flipped: IN7P is pulled to AVSS and IN7N pulled to AVDE     Channel 6 LOFF polarity flip     Flip the pullup/pulldown polarity of the current source or resi     on channel 6 for lead-off derivation.     0: No Flip: IN6P is pulled to AVDD and IN6N pulled to AVSS     1: Flipped: IN6P is pulled to AVSS and IN6N pulled to AVDD			
4	LOFF_FLIP5	RM	0h	Channel 5 LOFF polarity flip Flip the pullup/pulldown polarity of the current source or resistor on channel 5 for lead-off derivation. 0: No Flip: IN5P is pulled to AVDD and IN5N pulled to AVSS 1: Flipped: IN5P is pulled to AVSS and IN5N pulled to AVDD			
3	LOFF_FLIP4	R/W	0h	Channel 4 LOFF polarity flip Flip the pullup/pulldown polarity of the current source or resistor on channel 4 for lead-off derivation. 0: No Flip: IN4P is pulled to AVDD and IN4N pulled to AVSS 1: Flipped: IN4P is pulled to AVSS and IN4N pulled to AVDD			
2	LOFF_FLIP3	R/W	0h	Channel 3 LOFF polarity flip Flip the pullup/pulldown polarity of the current source or resistor on channel 3 for lead-off derivation. 0: No Flip: IN3P is pulled to AVDD and IN3N pulled to AVSS 1: Flipped: IN3P is pulled to AVSS and IN3N pulled to AVDD			
1	LOFF_FLIP2	R/W	0h	Channel 2 LOFF Polarity Flip Flip the pullup/pulldown polarity of the current source or resistor on channel 2 for lead-off derivation. 0: No Flip: IN2P is pulled to AVDD and IN2N pulled to AVSS 1: Flipped: IN2P is pulled to AVSS and IN2N pulled to AVDD			
0	LOFF_FLIP1	R/W	0h	Channel 1 LOFF Polarity Flip Flip the pullup/pulldown polarity of the current source or resistor on channel 1 for lead-off derivation. 0: No Flip: IN1P is pulled to AVDD and IN1N pulled to AVSS 1: Flipped: IN1P is pulled to AVSS and IN1N pulled to AVDD			

#### 9.6.12 LOFF\_STATP: Lead-Off Positive Signal Status Register (address = 12h) (reset = 00h)

This register stores the status of whether the positive electrode on each channel is on or off. See the Lead-Off Detection section for details. Ignore the LOFF\_STATP values if the corresponding LOFF\_SENSP bits are not set to 1. When the LOFF\_SENSEP bits are 0, the LOFF\_STATP bits should be ignored.

#### Figure 9.6.12. LOFF\_STATP: Lead-Off Positive Signal Status Register (Read-Only)

7	6	5	4	3	2	1	0
IN8P_OFF	IN7P_OFF	IN6P_OFF	IN5P_OFF	IN4P_OFF	IN3P_OFF	IN2P_OFF	IN1P_OFF
R-0h							



Bit	Field	Туре	Reset	Description
7	IN8P_OFF	R	Oh	Channel 8 positive channel lead-off status Status of whether IN8P electrode is on or off 0: Electrode is on 1: Electrode is off
6	IN7P_OFF	R	Oh	Channel 7 positive channel lead-off status Status of whether IN7P electrode is on or off 0: Electrode is on 1: Electrode is off
5	IN6P_OFF	R	Oh	Channel 6 positive channel lead-off status Status of whether IN6P electrode is on or off 0: Electrode is on 1: Electrode is off
4	IN5P_OFF	R	Oh	Channel 5 positive channel lead-off status Status of whether IN5P electrode is on or off 0: Electrode is on 1: Electrode is off
3	IN4P_OFF	R	Oh	Channel 4 positive channel lead-off status Status of whether IN4P electrode is on or off 0: Electrode is on 1: Electrode is off
2	IN3P_OFF	R	Oh	Channel 3 positive channel lead-off status Status of whether IN3P electrode is on or off 0: Electrode is on 1: Electrode is off
1	IN2P_OFF	R	Oh	Channel 2 positive channel lead-off status Status of whether IN2P electrode is on or off 0: Electrode is on 1: Electrode is off
0	IN1P_OFF	R	Oh	Channel 1 positive channel lead-off status Status of whether IN1P electrode is on or off 0: Electrode is on 1: Electrode is off

#### Table 9.6.13. Lead-Off Positive Signal Status Field Descriptions

# 9.6.1.13 LOFF\_STATN: Lead-Off Negative Signal Status Register (address = 13h) (reset = 00h)

This register stores the status of whether the negative electrode on each channel is on or off. See the Lead-Off Detection section for details. Ignore the LOFF\_STATN values if the corresponding LOFF\_SENSN bits are not set to 1. When the LOFF\_SENSEN bits are 0, the LOFF\_STATP bits should be ignored.

#### Figure 9.6.13. LOFF\_STATN: Lead-Off Negative Signal Status Register (Read-Only)

7	6	5	4	3	2	1	0
IN8N_OFF	IN7N_OFF	IN6N_OFF	IN5N_OFF	IN4N_OFF	IN3N_OFF	IN2N_OFF	IN1N_OFF
R-0h							



Bit	Field	Туре	Reset	Description
7	IN8N_OFF	R	Oh	Channel 8 negative channel lead-off status Status of whether IN8N electrode is on or off 0: Electrode is on 1: Electrode is off
6	IN7N_OFF	R	Oh	Channel 7 negative channel lead-off status Status of whether IN7N electrode is on or off 0: Electrode is on 1: Electrode is off
5	IN6N_OFF	R	Oh	Channel 6 negative channel lead-off status Status of whether IN6N electrode is on or off 0: Electrode is on 1: Electrode is off
4	IN5N_OFF	R	Oh	Channel 5 negative channel lead-off status Status of whether IN5N electrode is on or off 0: Electrode is on 1: Electrode is off
3	IN4N_OFF	R	Oh	Channel 4 negative channel lead-off status Status of whether IN4N electrode is on or off 0: Electrode is on 1: Electrode is off
2	IN3N_OFF	R	Oh	Channel 3 negative channel lead-off status Status of whether IN3N electrode is on or off 0: Electrode is on 1: Electrode is off
1	IN2N_OFF	R	Oh	Channel 2 negative channel lead-off status Status of whether IN2N electrode is on or off 0: Electrode is on 1: Electrode is off
0	IN1N_OFF	R	Oh	Channel 1 negative channel lead-off status Status of whether IN1N electrode is on or off 0: Electrode is on 1: Electrode is off

#### Table 9.6.14. Lead-Off Negative Signal Status Field Descriptions

#### 9.6.1.14 GPIO: General-Purpose I/O Register (address = 14h) (reset = 0Fh)

The general-purpose I/O register controls the action of the three GPIO pins. When RESP CTRL[1:0] is in mode 01 and 11, the GPIO2, GPIO3, and GPIO4 pins are not available for use. Figure 9.6.14. GPIO: General-Purpose I/O Register

7	6	5	4	3	2	1	0
GPIOD[4:1]					GPIO	C[4:1]	
	R/W-0h				R/M	/-Fh	

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

#### Table 9.6.15. General-Purpose I/O Field Descriptions

Bit	Field	Туре	Reset	Description
7:4	GPIOD[4:1]	R/W	0h	GPIO data These bits are used to read and write data to the GPIO ports. When reading the register, the data returned correspond to the state of the GPIO external pins, whether they are programmed as inputs or as outputs. As outputs, a write to the GPIOD sets the output value. As inputs, a write to the GPIOD has no effect. GPIO is not available in certain respiration modes.
3:0	GPIOC[4:1]	R/W	Fh	GPIO control (corresponding GPIOD) These bits determine if the corresponding GPIOD pin is an input or output. 0 = Output 1 = Input



#### 9.6.15 MISC1: Miscellaneous 1 Register (address = 15h) (reset = 00h)

This register provides the pace controls that configure the channel signal used to feed the external pace detect circuitry. See the Pace Detect section for details.

#### Figure 9.6.15. PACE: Pace Detect Register

7	6	5	4	3	2	1	0
0	0	SRB1	0	0	0	0	0
R/W-0h							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

#### Table 9.6.16. Miscellaneous 1 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7:6	Reserved	R/W	Oh	Reserved Always write 0h
5	SRB1	R/W	Oh	Stimulus, reference, and bias 1 This bit connects the SRB1 to all 4, 6, or 8 channels inverting inputs 0 : Switches open 1 : Switches closed
4:0	Reserved	R/W	0h	Reserved Always write 0h

#### 9.6.16 MISC2: Miscellaneous 2(address = 16h) (reset = 00h)

This register is reserved for future use.

#### Figure 9.6.16. MISC1: Miscellaneous 1 Register

7	6	5	4	3	2	1	0
0	0	0	0	0	0	0	0
R/W-0h							

LEGEND: R/W = Read/Write; R = Read only; -n = value after reset

#### Table 9.6.17. Miscellaneous 1 Register Field Descriptions

Bit	Field	Туре	Reset	Description	
7:0	hold	R/W	0h	Reserved	
				Always write 0h	

9.6.17 CONFIG4: Configuration Register 4 (address = 17h) (reset = 00h)

#### Figure 9.6.17. CONFIG4: Configuration Register 4

7	6	5	4	3	2	1	0
0	0	0	0	SINGLE_SHOT	0	PD_LOFF_ COMP	0
R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h	R/W-0h



Bit	Field	Туре	Reset	Description	
7:4	Reserved	R/W	Oh	Reserved Always write 0h	
3	SINGLE_SHOT	R/W	Oh	Single-shot conversion This bit sets the conversion mode. 0 : Continuous conversion mode 1 : Single-shot mode	
2	Reserved	R/W	0h	Reserved Always write 0h	
1	PD_LOFF_COMP	R/W	Oh	Lead-off comparator power-down This bit powers down the lead-off comparators. 0 : Lead-off comparators disabled 1 : Lead-off comparators enabled	
0	Reserved	R/W	0h	Reserved Always write 0h	

#### Table 9.6.18. Configuration Register 4 Field Descriptions

### **Applications matters**

#### NOTE :

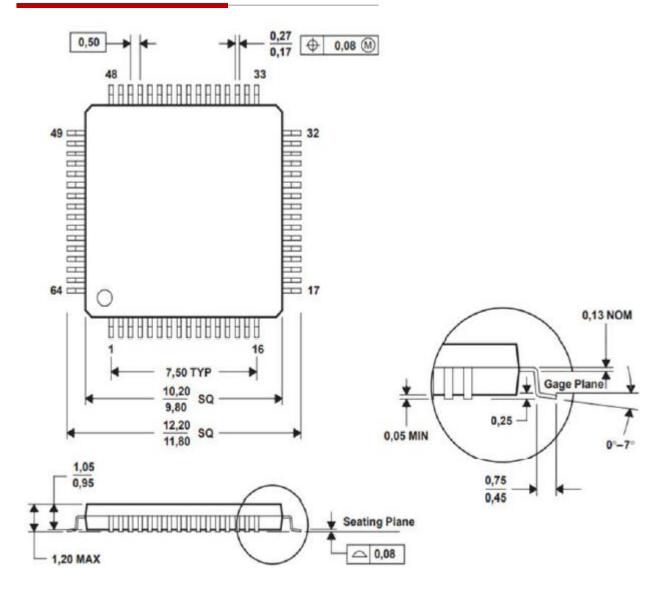
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI' s customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.



CBM24AD99Q

OPERATION INSTRUCTION

# **Outline Dimensions**





# Package/Ordering Information

MODEL	ORDERING NUMBER	TEMPERATURE	PACKAGE DESCRIPTION	PAKEAGE OPTION	MAKING INFORMATION
CBM24AD99Q		-40℃~85℃	LQFP-64	Tray, 960	
CBM24AD99Q		-40℃~85℃	LQFP-64	Tray, 960	
CBM24AD99Q		-40°C~85°C	LQFP-64	Tray, 960	